



# **64Mb Dual Quad SPI MRAM**

**Dual-Quad SPI MRAM**

**1.8V**

- **S3H6408R1M**
- **S3H6408R2M**

**Datasheet**

## Feature

- 64Mb: Dual Stack of two 32Mb
- Serial Peripheral Interface with Mode 0 and Mode 3
  - Dual-Quad SPI
  - Single and double data rate (SDR/DDR)
- Performance
  - 150MHz for SDR
  - 75MHz for DDR
- Supports XIP for read and write operations
- Data protection
  - WP# pin write protection
  - Block lock protection
- Nonvolatile status and configuration registers
- Identification
  - Unique ID
  - Serial number - user writable
- Memory cell : STT-MRAM
- Density
  - 64Mb
- Data Integrity : No external ECC required
- Data Endurance
  - Unlimited read cycle
  - $10^{14}$  write cycles
- Data Retention
  - 20 years at 85°C
- Single Power Supply Operation
  - 1.71V~1.98V
- Operating Temperature Range
  - Industrial Temperature: -40°C to 85°C
- RoHS compliant package
  - 24 FBGA (6mm x 8mm)

## Performance

| Operation                                | Typical Values | Units |
|------------------------------------------|----------------|-------|
| Frequency(SDR)                           | 150(Max.)      | MHz   |
| Frequency(DDR)                           | 75(Max.)       | MHz   |
| Standby Current                          | 1.2            | mA    |
| Deep Power Down Current                  | 120            | uA    |
| Active Read Current (8-8-8) SDR @150MHz  | 18             | mA    |
| Active Write Current (8-8-8) SDR @150MHz | 48             | mA    |
| Active Read Current (8-8-8) DDR @75MHz   | 18             | mA    |
| Active Write Current (8-8-8) DDR @75MHz  | 48             | mA    |

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## 1. General Description

The device is a Spin-Transfer-Torque Magneto-resistive Random Access Memory (STT-MRAM).

It features a SPI bus interface, XIP (execute-in-place) functionality and hardware and software based data protection mechanisms.

SPI (Serial Peripheral Interface) is a synchronous serial communication interface with command, address, and data signals.

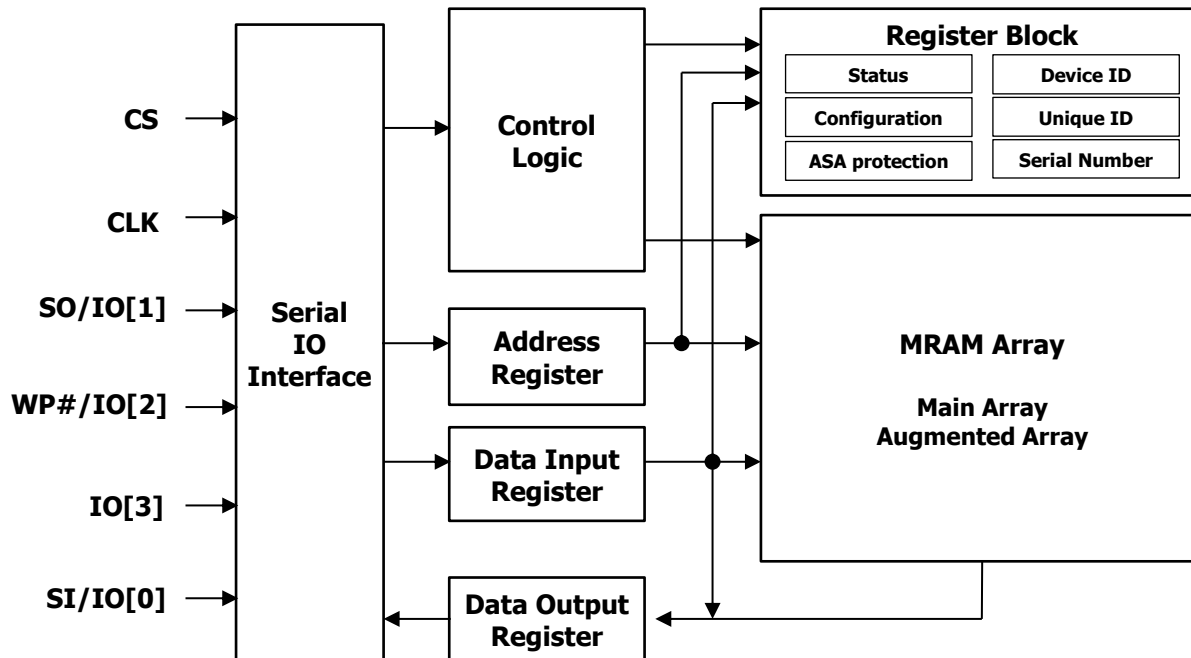
Dual-quad SPI devices consist of two 32Mb quad SPI devices, providing 8-bit I/O data access. Both 1-CS#/1-CLK and 2-CS#/2-CLK configurations are supported for convenient system configuration.

Each individual die provides various SPI modes, allowing options for bandwidth expansion. Extended SPI mode has single pin for command signal for each die. User can select an option for how many pins to be allocated to address and data signals among 1 pin or 4 pins for each die. Quad SPI mode provides 4 pins for command, address, and data signals for each individual die.

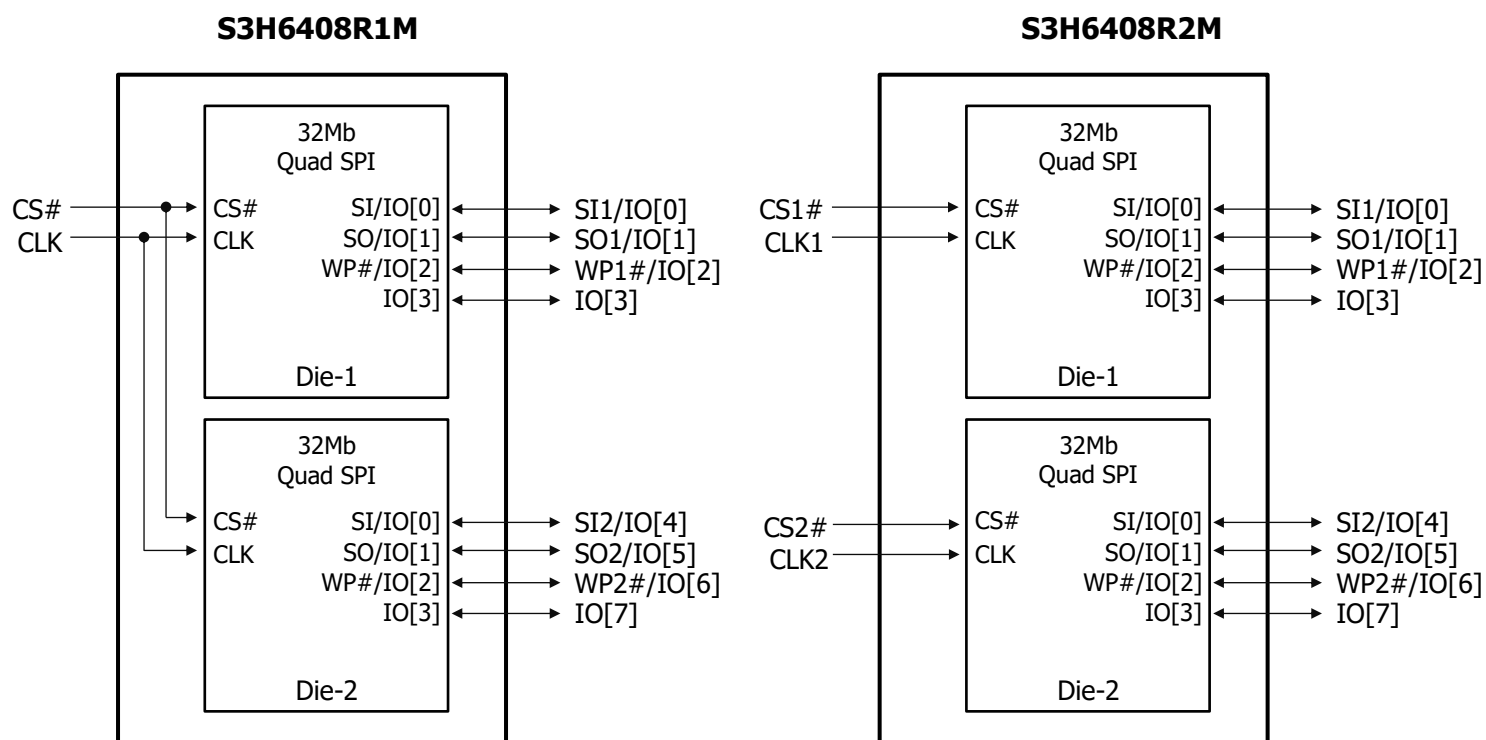
Each individual die has its own nonvolatile register bits – status register, configuration register, serial number register, augmented 512-byte register, protection register for augmented bytes, device ID, and unique ID. The status register and configuration register are required to be set at least once on power-up after high temperature solder-reflow process for each individual die.

The device is available in small footprint 24 FBGA package. The package is compatible with similar non-volatile products. The device is offered with an industrial (-40°C to 85°C) operating temperature range.

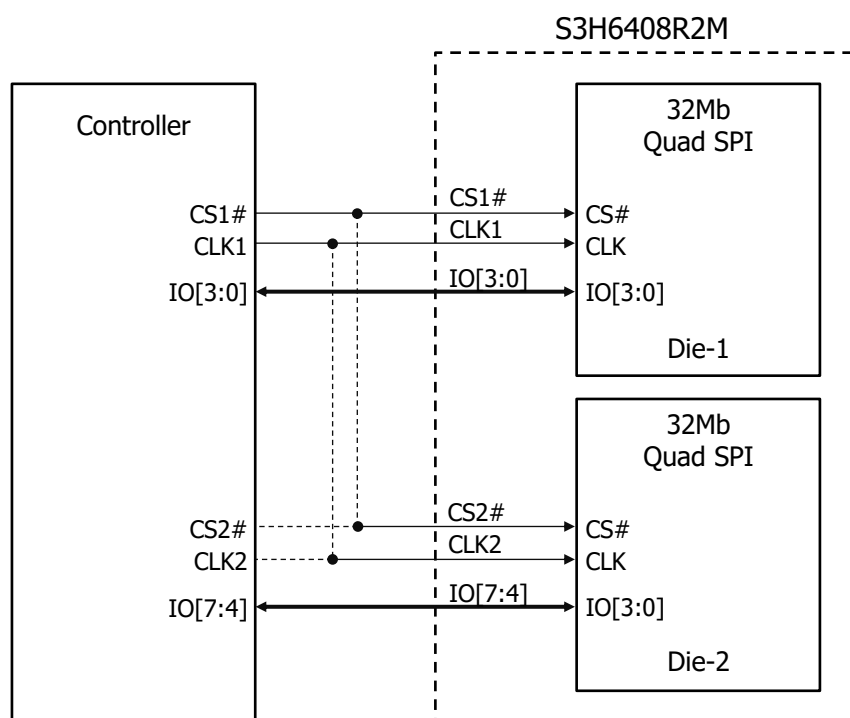
**Figure 1: Functional Block Diagram**



Functional Block Diagram for each individual die (32Mb)

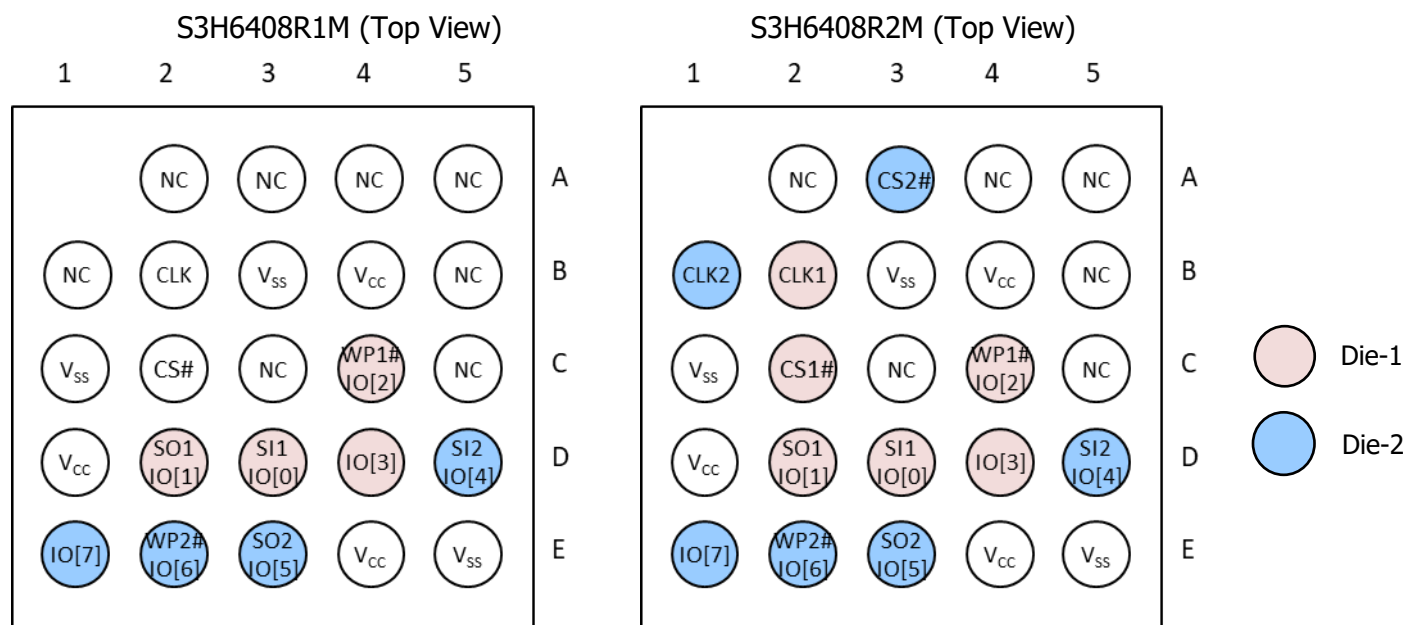


**Figure 2: Proposed connection for S3H6408R2M device**



## 2. Pin Configuration

**Figure 3: 24-Ball FBGA, 5x5 (Balls Down)**



**Table 1: Pin Description**

| Pin                          | Type                  | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
|------------------------------|-----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>CS# or CS1#, CS2#</b>     | Input                 | <b>Chip Select:</b> When CS# is driven Low, a read or write operation is initiated. When CS# is driven High, the device enters standby mode, and all other input pins are ignored and the output pins are tri-stated. CS# should be High at power-up to prevent abnormal write operation. This pin does not have internal pull-up resistor.                                                                                                                                                                                                                                             |
| <b>CLK or CLK1, CLK2</b>     | Input                 | <b>Clock:</b> In SDR (single data rate) mode, the command, address, and data inputs are latched on the rising edge of the clock. Data is output on the falling edge of the clock. In DDR (double data rate) mode, the command is latched on the rising edge of the clock and address and data inputs are latched on the rising and falling edges of the clock. Similarly, data is output on both edges of the clock. The two SPI clock modes are supported as follows.<br><ul style="list-style-type: none"> <li>• SPI Mode 0 : SDR and DDR</li> <li>• SPI Mode 3 : SDR only</li> </ul> |
| <b>WP1#/IO[2] WP2#/IO[6]</b> | Input /Bidirectional  | <b>Write Protect (Extended SPI):</b> The writing of status and configuration register is protected in related with WP# and WPEN. See "Table 7: Write Protection Modes". This pin does not have an internal pull-up resistor, it cannot be left floating and must be driven. WP# is valid in Extended SPI.<br><b>IO[2], IO[6] :</b> The bidirectional I/O in Quad input/output mode.                                                                                                                                                                                                     |
| <b>IO[3], IO[7]</b>          | Bidirectional         | <b>IO[3], IO[7] :</b> The bidirectional I/O in Quad input/output modes.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| <b>SI1/IO[0] SI2/IO[4]</b>   | Input /Bidirectional  | <b>SI1, SI2:</b> The serial input in Single input mode.<br><b>IO[0], IO[4] :</b> The bidirectional I/O in Quad input/output modes                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| <b>SO1/IO[1] SO2/IO[5]</b>   | Output /Bidirectional | <b>SO1, SO2 :</b> The serial data output in Single output mode.<br><b>IO[1], IO[5] :</b> The bidirectional in Quad input/output modes.                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| <b>Vcc</b>                   | Supply                | Power pin                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| <b>Vss</b>                   | Supply                | Ground pin                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |

### 3. Power On/Off Sequence

During power-up, power-down or power-loss, CS# for S3H6404R1M or CS1# and CS2# for S3H6404R2M must follow Vcc to ensure data protection.

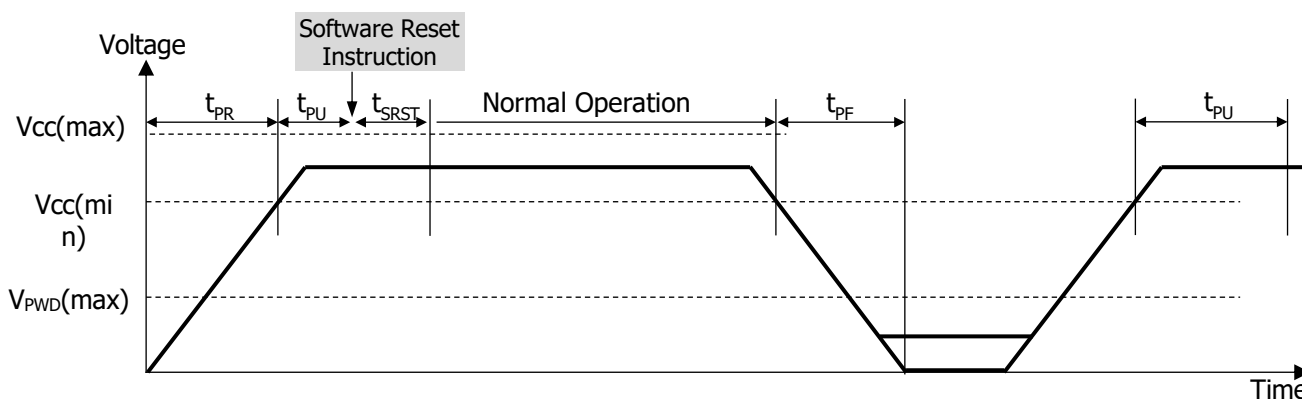
It is recommended that CS# or both CS1# and CS2# must follow Vcc when Vcc is below Vcc(minimum) and during  $t_{PU}$ .

A 10K $\Omega$  pull-up resistor between Vcc and CS# or CS1# and CS2# pin is recommended.

Software reset operation is required after  $t_{PU}$  for both dies.

Normal operation must start after  $t_{SRST}$ .

**Figure 4: Power-up/down Behavior**



**Table 2: Power Up/Down Timing**

| Parameter                                                            | Symbol           | Min  | Max  | Units     |
|----------------------------------------------------------------------|------------------|------|------|-----------|
| Vcc Range                                                            | Vcc              | 1.71 | 1.98 | V         |
| Vcc rising time                                                      | $t_{PR}^{(1)}$   | 30   | -    | $\mu s/V$ |
| Vcc falling time                                                     | $t_{PF}^{(1)}$   | 30   | -    | $\mu s/V$ |
| Vcc(min) to CS# Low (first instruction) time                         | $t_{PU}^{(1)}$   | 2.0  | -    | ms        |
| Vcc needed to below $V_{PWD}$ for ensuring initialization will occur | $V_{PWD}^{(1)}$  | -    | 0.8  | V         |
| Software Reset time                                                  | $V_{SRST}^{(1)}$ | 2.0  |      | ms        |

**Notes:**

1. These parameters are guaranteed by characterization; not tested in production.

## 4. Memory Organization

**Table 3: Memory Map**

| Density                      | Address Range      | 24-bit Address [23:0] |                      |
|------------------------------|--------------------|-----------------------|----------------------|
| 32Mb<br>-each individual die | 000000h – 3FFFFFFh | [23:22] – Logic '0'   | [21:0] – Addressable |

**Table 4: Augmented Area Map**

| Augmented Area                   | Address Range     | 24-bit Address [23:0] |                     |
|----------------------------------|-------------------|-----------------------|---------------------|
| 512-byte<br>-each individual die | 000000h – 0001FFh | [23:9] – Logic '0'    | [8:0] – Addressable |

**Notes:**

- The augmented 512-byte area is divided into 8 individually readable and writable sections (64 bytes per section). After an individual section is written, it can be protected individually to prevent further writing. The address bits Address[23:9] must be logic '0'.

**Table 5: Register Address Map**

The device provides the register read/write instructions to read and write data of each register.

In addition, the device provides the register read and/or write function based on addresses using RDAR(65h) and WRAR(71h) commands.

| Register Name                  | Address for each individual die |
|--------------------------------|---------------------------------|
| Status Register                | 0x000000h                       |
| Configuration Register 1       | 0x000002h                       |
| Configuration Register 2       | 0x000003h                       |
| Configuration Register 3       | 0x000004h                       |
| Configuration Register 4       | 0x000005h                       |
| Device Identification Register | 0x000030h                       |
| Unique Identification Register | 0x000040h                       |
| Serial Number Register         | 0x000080h                       |

**Notes:**

- Register address space is different from the memory array and augmented 512-byte area.

## 5. Register Description

Each individual die has its own nonvolatile register – Status Register, Configuration Register, Serial Number Register, Augmented Area Register, Protection Register for augmented area, Device ID, and Unique ID. The nonvolatile bits of Status Register and Configuration Register are required to be set at least once on power-up after high temperature solder-reflow process for both dies. The device configuration is set from Status Register and Configuration Registers after power-up or by Write Register instructions. The following descriptions apply to each individual die.

### 5.1 Status Register

The device offers both hardware and software based data protection schemes. Hardware protection is through WP# pin. Software protection is controlled by configuration bits in the Status register. Both schemes inhibit writing to the registers, memory and augmented area. Status Register contains options for enabling/disabling data protection. By controlling configuration bits in Status Register, user can protect data in memory based on software protection schemes. The Status Register can be written using either the Write Status Register instruction or Write Any Register (Address based) instruction combined with CR1[2] of Configuration Register 1, and it can be read using either Read Status Register instruction or Read Any Register(Address based) instruction.

**Table 6: Status Register**

| Bits  | Name  | Read/Write | Default State | Description                                                                                                                                                |
|-------|-------|------------|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SR[7] | WPEN  | R/W        | -             | Hardware Based WP# Protect Bit<br>1: Protection Enabled – write protects when WP# is Low<br>0: Protection Disabled – Doesn't write protect when WP# is Low |
| SR[6] | SNPEN | R/W        | -             | Serial Number Protect Bit<br>1: Serial Number Write protected<br>0: Serial Number Writable                                                                 |
| SR[5] | TB    | R/W        | -             | Top/Bottom Memory Array Protect Selection<br>1: Bottom Protection Enabled (Lower Address Range)<br>0: Top Protection Enabled (Higher Address Range)        |
| SR[4] | BP[2] | R/W        | -             | Block Protection Bits                                                                                                                                      |
| SR[3] | BP[1] | R/W        | -             |                                                                                                                                                            |
| SR[2] | BP[0] | R/W        | -             |                                                                                                                                                            |
| SR[1] | WREN  | R          | 0             | Write Protection Enable<br>1: Write Operation Protection Disabled<br>0: Write Operation Protection Enabled                                                 |
| SR[0] | RSVD  | R          | -             | Reserved for future use                                                                                                                                    |

**Notes:**

1. SR[7:2] are nonvolatile bits.
2. TB and BP[2:0] can be protected by CR1[2] of Configuration Register 1.

### 5.1.1 Write Protection Modes

WPEN bit (SR[7]) is used in conjunction with the WREN bit (SR[1]) and the WP# pin to provide hardware block protection. SR[7:2] will remain set from the nonvolatile registers whenever the power is on. The WREN bit is volatile and set to '1' by the Write Enable command. It is reset to '0' after power up, software reset, JEDEC reset, Write Disable command or when Write Register operation finishes. For WREN information on write operations for memory and augmented area, please refer to Configuration Register 4.

The device enters hardware protection when the WP# input is Low and the WPEN bit of Status Register is set to '1', and the nonvolatile registers cannot be changed. The device exits from hardware protection when the WP# pin goes High or WPEN bit is set to '0' and the register bits can be changed.

**Table 7: Write Protection Modes**

| WREN | WPEN | WP# | Registers <sup>(1)</sup> | Memory <sup>(2)</sup> and Augmented 512-byte Area <sup>(3)</sup> |                  |
|------|------|-----|--------------------------|------------------------------------------------------------------|------------------|
|      |      |     |                          | Protected Area                                                   | Unprotected Area |
| 0    | X    | X   | Protected                | Protected                                                        | Protected        |
| 1    | 0    | X   | Unprotected              | Protected                                                        | Unprotected      |
| 1    | 1    | 0   | Protected                | Protected                                                        | Unprotected      |
| 1    | 1    | 1   | Unprotected              | Protected                                                        | Unprotected      |

**Notes:**

1. Status, Configuration, Protection for Augmented 512-Byte Area and Serial Number Register.
2. Memory address range protection based on Block Protection Bits
3. The Augmented 512-byte Area range protection based on Augmented 512-Byte Area Protection Register.  
The Augmented 512-byte Area can also be protected by CR1[0] of Configuration Register 1.
4. The Serial Number register can also be protected by SR[6] of Status Register.
5. X: Don't Care – can be logic '0' or '1'
6. Protected: write protected, Unprotected: writable

### 5.1.2 Block Protection

The write protection blocks for the memory array are determined by the status register bits (TB and BP[2:0]) as Table 8 below. TB and BP[2:0] can be modified by Write Status Register instruction(01h) or Write Any Register instruction(71h) when the WP# is High or the Status Register WPEN bit is set to 0 and CR1[2] of Configuration Register 1 is set to '0'.

**Table 8: Block Protection Address Range Selection**

| TB  | BP[2] | BP[1] | BP[0] | Protected Portion | 32Mb<br>for each individual die |
|-----|-------|-------|-------|-------------------|---------------------------------|
| 0/1 | 0     | 0     | 0     | None              | None                            |
| 0   | 0     | 0     | 1     | Upper 1/64        | 3F0000h – 3FFFFFFh              |
| 0   | 0     | 1     | 0     | Upper 1/32        | 3E0000h – 3FFFFFFh              |
| 0   | 0     | 1     | 1     | Upper 1/16        | 3C0000h – 3FFFFFFh              |
| 0   | 1     | 0     | 0     | Upper 1/8         | 380000h – 3FFFFFFh              |
| 0   | 1     | 0     | 1     | Upper 1/4         | 300000h – 3FFFFFFh              |
| 0   | 1     | 1     | 0     | Upper 1/2         | 200000h – 3FFFFFFh              |
| 1   | 0     | 0     | 1     | Lower 1/64        | 000000h – 00FFFFh               |
| 1   | 0     | 1     | 0     | Lower 1/32        | 000000h – 01FFFFh               |
| 1   | 0     | 1     | 1     | Lower 1/16        | 000000h – 03FFFFh               |
| 1   | 1     | 0     | 0     | Lower 1/8         | 000000h – 07FFFFh               |
| 1   | 1     | 0     | 1     | Lower 1/4         | 000000h – 0FFFFFFh              |
| 1   | 1     | 1     | 0     | Lower 1/2         | 000000h – 1FFFFFFh              |
| 0/1 | 1     | 1     | 1     | All               | 000000h – 3FFFFFFh              |

### 5.1.3 Augmented Area Protection

The Augmented Area Protection register contains options for enabling/disabling data protection for eight sections.

**Table 9: Augmented Area Protection Register – Read and Write**

| Bits   | Name    | Address Range<br>for each individual die | Read/<br>Write | Default<br>State | Description                                     |
|--------|---------|------------------------------------------|----------------|------------------|-------------------------------------------------|
| ASP[7] | ASPS[7] | 0001C0h – 0001FFh                        | R/W            | 0                | 1: Protection Enabled<br>0: Protection Disabled |
| ASP[6] | ASPS[6] | 000180h – 0001BFh                        | R/W            | 0                |                                                 |
| ASP[5] | ASPS[5] | 000140h – 00017Fh                        | R/W            | 0                |                                                 |
| ASP[4] | ASPS[4] | 000100h – 00013Fh                        | R/W            | 0                |                                                 |
| ASP[3] | ASPS[3] | 0000C0h – 0000FFh                        | R/W            | 0                |                                                 |
| ASP[2] | ASPS[2] | 000080h – 0000BFh                        | R/W            | 0                |                                                 |
| ASP[1] | ASPS[1] | 000040h – 00007Fh                        | R/W            | 0                |                                                 |
| ASP[0] | ASPS[0] | 000000h – 00003Fh                        | R/W            | 0                |                                                 |

**Notes:**

- ASP[7:0] are nonvolatile bits.

## 5.2 Configuration Register

The Configuration Register can be configured using either the Write Configuration Register instructions or Write Any Register (Address based) instruction, and it can be read using either Read Configuration Register instructions or Read Any Register(Address based) instruction.

### 5.2.1 Configuration Register 1

Configuration Register 1 controls the locking and unlocking of data protection options set in the Status Register and Augmented 512-Byte Area Protection Register. Once locked, these protection options cannot be changed in the Status register.

**Table 10: Configuration Register 1**

| Bits     | Name  | Read/Write | Default State | Selection Options                                                                                                                                                         |
|----------|-------|------------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CR1[7:3] | RSVD  | R/W        | -             | Reserved for future use                                                                                                                                                   |
| CR1[2]   | MAPLK | R/W        | -             | Status Register TB, BP[2:0] Protect<br>1: Lock TB and BP[2:0]<br>0: Unlock TB and BP[2:0]                                                                                 |
| CR1[1]   | RSVD  | R/W        | -             | Reserved for future use                                                                                                                                                   |
| CR1[0]   | ASPLK | R/W        | -             | Augmented Area Data Protection<br>1: Write Protection for Augmented Area Data regardless of ASP[7:0]<br>0: Write Protection for Augmented Area Data depending on ASP[7:0] |

**Notes:**

1. CR1[7:0] are nonvolatile bits.

### 5.2.2 Configuration Register 2

Configuration Register 2 controls the interface types along with memory array access latency.

**Table 11: Configuration Register 2**

| Bits   | Name  | Read/Write | Default State | Description                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|--------|-------|------------|---------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CR2[7] | RSVD  | R/W        | -             | Reserved for future use                                                                                                                                                                                                                                                                                                                                                                                                                                |
| CR2[6] | QPIEN | R          | 0             | Quad SPI (QPI 4-4-4) Interface Mode<br>1: Quad SPI (QPI 4-4-4) Enabled<br>0: Extended SPI (SPI 1-X-X) Enabled                                                                                                                                                                                                                                                                                                                                          |
| CR2[5] | RSVD  | R/W        | 0             | It must be written as '0'                                                                                                                                                                                                                                                                                                                                                                                                                              |
| CR2[4] | RSVD  | R          | 0             | Reserved for future use                                                                                                                                                                                                                                                                                                                                                                                                                                |
| CR2[3] | RL[3] | R/W        | -             | Read Latency Selection Bits<br>0000: 0 Cycle                      1000: 8 Cycles<br>0001: 1 Cycle                     1001: 9 Cycles<br>0010: 2 Cycles                  1010: 10 Cycles<br>0011: 3 Cycles                  1011: 11 Cycles<br>0100: 4 Cycles                  1100: 12 Cycles<br>0101: 5 Cycles                  1101: 13 Cycles<br>0110: 6 Cycles                  1110: 14 Cycles<br>0111: 7 Cycles                  1111: 15 Cycles |
| CR2[2] | RL[2] |            | -             |                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| CR2[1] | RL[1] |            | -             |                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| CR2[0] | RL[0] |            | -             |                                                                                                                                                                                                                                                                                                                                                                                                                                                        |

**Notes:**

1. Read Latency is frequency-dependent.
2. Read(03h) does not depend on the Read latency Selection Bits CR2[3:0].
3. CR2[7,5,3:0] are non-volatile bits.
4. CR2[5] must be written as '0'.

The number of read latency cycles must be set to accord with the clock frequency for all Read Memory instructions (except for Read 03h) and Read Augmented 512-Byte Area (4Bh). Insufficient read latency cycles for the operating frequency causes the device to read incorrect data.

**Table 12: Read Latency Cycles vs. Maximum Frequency (Memory Area)**

| Read Latency Cycles | SDR      |                      |          | DDR      |          |                      | Unit |
|---------------------|----------|----------------------|----------|----------|----------|----------------------|------|
|                     | 1s-1s-1s | 1s-1s-4s<br>1s-4s-4s | 4s-4s-4s | 1s-1d-1d | 1s-1d-4d | 1s-4d-4d<br>4s-4d-4d |      |
| 0                   | 108      | 20                   | 20       | -        | -        | -                    | MHz  |
| 1                   | 125      | 33                   | 33       | 54       | -        | -                    | MHz  |
| 2                   | 125      | 50                   | 50       | 66       | 33       | 33                   | MHz  |
| 3                   | 125      | 66                   | 66       | 75       | 40       | 40                   | MHz  |
| 4                   | 125      | 83                   | 83       | 75       | 54       | 54                   | MHz  |
| 5                   | 125      | 100                  | 100      | 75       | 54       | 54                   | MHz  |
| 6                   | 125      | 108                  | 108      | 75       | 54       | 66                   | MHz  |
| 7                   | 125      | 108                  | 125      | 75       | 54       | 66                   | MHz  |
| 8                   | 125      | 108                  | 125      | 75       | 54       | 66                   | MHz  |
| 9                   | 125      | 108                  | 125      | 75       | 54       | 75                   | MHz  |
| 10                  | 133      | 108                  | 133      | 75       | 54       | 75                   | MHz  |
| 11~15               | 150      | 108                  | 150      | 75       | 54       | 75                   | MHz  |

**Notes:**

1. Read(03h) does not depend on Read latency Selection Bits CR2[3:0]. The latency of Read(03h) is always 0-cycle.

**Table 13: Read Latency Cycles vs. Maximum Frequency (Augmented Area)**

| Read Latency Cycles | RDAS 4Bh | Unit |
|---------------------|----------|------|
|                     | 1s-1s-1s |      |
| 0~2                 | NA       | -    |
| 3                   | 33       | MHz  |
| 4                   | 54       | MHz  |
| 5                   | 66       | MHz  |
| 6                   | 83       | MHz  |
| 7                   | 100      | MHz  |
| 8                   | 108      | MHz  |
| 9                   | 125      | MHz  |
| 10                  | 133      | MHz  |
| 11~15               | 150      | MHz  |

**Table 14: Read Latency Cycles vs. Maximum Frequency (Read Any Register)**

| Read Type           | XIP | Latency Cycles | Max Frequency |
|---------------------|-----|----------------|---------------|
| 1s-1s-1s (RDAR 65h) | -   | 8              | 150MHz        |
| 4s-4s-4s (RDAR 65h) | -   | 2              | 150MHz        |

**Notes:**

1. RDAR(65h, read any register instruction) does not depend on Read latency Selection Bits CR2[3:0].

### 5.2.3 Configuration Register 3

Configuration Register 3 controls the output driver strength along with the boundary size of read data wrapping.

**Table 15: Configuration Register 3**

| Bits   | Name    | Read/Write | Description                                                                                                                                                                                                |
|--------|---------|------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CR3[7] | DRV[2]  | R/W        | Output Driver Strength Selection DRV[2:0]<br>1.8V<br>000: 35Ω<br>001: 95Ω<br>010: 63Ω<br>011: 50Ω<br>100: 40Ω<br>101: 30Ω<br>110: 26Ω<br>111: 22Ω                                                          |
| CR3[6] | DRV[1]  |            |                                                                                                                                                                                                            |
| CR3[5] | DRV[0]  |            |                                                                                                                                                                                                            |
| CR3[4] | WRPEN   | R/W        | Read WRAP Enable<br>1: Read Wrap Enabled<br>0: Read Wrap Disabled                                                                                                                                          |
| CR3[3] | RSVD    | R/W        | Reserved for future use                                                                                                                                                                                    |
| CR3[2] | WRPL[2] | R/W        | Wrap length configuration WRPL[2:0]<br>000: 16-byte wrap<br>001: 32-byte wrap<br>010: 64-byte wrap<br>011: 128-byte wrap<br>100: 256-byte wrap<br>101: 512-byte wrap<br>110: 1K-byte wrap<br>111: Reserved |
| CR3[1] | WRPL[1] |            |                                                                                                                                                                                                            |
| CR3[0] | WRPL[0] |            |                                                                                                                                                                                                            |

**Notes:**

1. Default output strength is DRV[2:0]=000.
2. CR3[7:0] are non-volatile bits.

|                        | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| WRPEN(CR3[4])<br>=Low  | Read and write operation: continuous mode<br>Read or write operation starts at the input address, and once the address reaches the maximum address boundary, it automatically returns to minimum address (000000h) until CS# goes to High.                                                                                                                                                                                                                                                                                                                                                   |
| WRPEN(CR3[4])<br>=High | Read operations: wrap mode<br>Read wrap mode is enabled when WRPEN(CR3[4]) is High, and the read data wrap length is controlled by WRPL[2:0]. The output data starts at the input address, data are output sequentially. Once it reaches the ending boundary, the output will wrap around to the beginning boundary automatically until CS# is pulled High.<br><br>Write operation: continuous mode<br>Write operation starts at the input address, and once the address reaches the maximum address boundary, it automatically returns to minimum address (000000h) until CS# goes to High. |

### 5.2.4 Configuration Register 4

Configuration Register 4 controls Write Protection Enable/Disable (WREN) functionality during memory and augmented area writes.

This functionality makes SPI MRAM compatible to other SPI devices.

**Table 16: Configuration Register 4**

| Bits     | Name     | Read/Write | Default State | Selection Options                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|----------|----------|------------|---------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CR4[7:2] | RSVD     | R/W        | -             | Reserved for future use                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| CR4[1]   | WRENS[1] | R/W        | -             | 00: Normal mode<br>WREN is prerequisite for every Memory or Augmented Area Write instruction (WREN is reset after CS# goes High).<br>01: SRAM mode<br>WREN is not a prerequisite for Memory Write or Augmented Area Write instructions (WREN is ignored).<br>10: Back-to-Back mode<br>WREN is prerequisite only to the first Memory Write or Augmented Area Write instruction. To reset WREN, WREN Disable instruction must be executed. (WREN does not reset after CS# goes High).<br>11: Reserved |
| CR4[0]   | WRENS[0] |            | -             |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |

**Notes:**

- Write Protection Enable (WREN – Status Register) for Register is maintained irrespective of the Configuration Register 4 settings.  
In other words, all register write Instructions require WREN to be set, and WREN is reset after CS# goes High.  
CR4[1:0] only affects writing for memory and augmented area.
- CR4[7:0] are nonvolatile bits.

## 5.3 Device Identification Register

Each individual die has Device Identification register which contains Netsol's Manufacturing ID along with device configuration information.

**Table 17: Device Identification Register**

| Bits     | Manufacturer ID | Device Configuration |           |           |          |          |
|----------|-----------------|----------------------|-----------|-----------|----------|----------|
| ID[31:0] | ID[31:24]       | Interface            | Voltage   | Reserved  | Density  | Reserved |
|          |                 | ID[23:20]            | ID[19:16] | ID[15:12] | ID[11:8] | ID[7:0]  |

| Manufacturer ID | Interface       | Voltage     | Reserved | Density     | Reserved |
|-----------------|-----------------|-------------|----------|-------------|----------|
| 31-24           | 23-20           | 19-16       | 15-12    | 11-8        | 7-0      |
| 1101 1001       | 0000 : Quad SPI | 0010 : 1.8V | 0000     | 0110 : 32Mb | 00000001 |

## 5.4 Serial Number Register

Each individual die provides 64-bit Serial Number register and the user can write it.

**Table 18: Serial Number Register**

| Bits     | Name | Description         | Read/ Write | State         |
|----------|------|---------------------|-------------|---------------|
| SN[63:0] | SN   | Serial Number Value | R/W         | User writable |

**Notes:**

1. Serial Number Bits are nonvolatile.
2. User should write the data after solder-reflow process, if used.

## 5.5 Unique Identification Register

Unique Identification register contains a number unique for each individual die.

**Table 19: Unique ID Register**

| Bits      | Name | Read/Write | Description                                                                                                           |
|-----------|------|------------|-----------------------------------------------------------------------------------------------------------------------|
| UID[63:0] | UID  | R          | Unique Identification Number Value<br>The value stored is factory-written in the factory and specific to each device. |

## 6. SPI Protocol

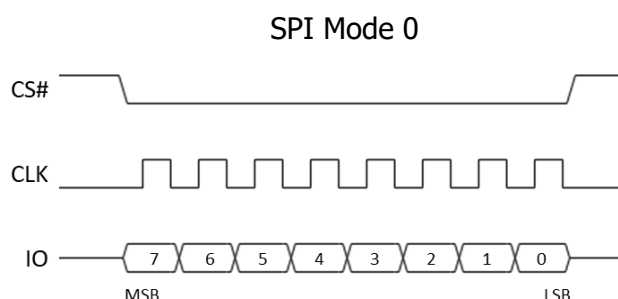
All communication between a host and the device occurs through commands. The commands define the operations that need to be executed. Instructions consist of a command followed by an optional address modifier and the associated data, which are transferred sequentially. To initiate a command, CS# should be driven Low and CLK should be toggled. When the correct command is input to this device, it enters active mode and remains in that state until next CS# rising edge. When CS# goes High, the device goes into standby mode.

### 6.1 SPI Clock Modes

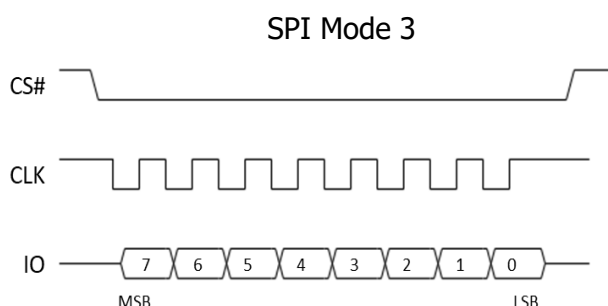
The following two SPI clock modes are supported.

- SPI Mode 0 (CPOL = 0, CPHA = 0) – SDR and DDR
- SPI Mode 3 (CPOL = 1, CPHA = 1) – SDR only

**Figure 5: SPI Clock Modes**



Mode0: Clock stays in Low level during idle state and starts toggling by going High.



Mode 3: Clock stays in High level during idle state and starts toggling by going Low.

## 6.2 SPI Interface Modes

Each individual die supports 2 categories of SPI interface modes.

1. Extended SPI: the command is transferred through one pin.
  - 1) Address and data are transferred through one pin (1-1-1).
  - 2) Address is transferred through one pin, data is transferred through four pins (1-1-4).
  - 3) Address and data are transferred through four pins (1-4-4).
2. Quad SPI: All command, address and data are transferred through four pins (4-4-4).

The device supports DDR (double data rate) for address and data.

**Table 20: Pin Assignment / Interface Modes**

| Instruction Component | Interface Modes (Command-Address-Data) |                      |                      |                     |
|-----------------------|----------------------------------------|----------------------|----------------------|---------------------|
|                       | Extended SPI                           |                      |                      | Quad SPI            |
|                       | 1s-1s-1s<br>1s-1d-1d                   | 1s-1s-4s<br>1s-1d-4d | 1s-4s-4s<br>1s-4d-4d | 4s-4s-4s<br>4s-4-4d |
| Command               | SI/IO[0]                               | SI/IO[0]             | SI/IO[0]             | IO[3:0]             |
| Address               | SI/IO[0]                               | SI/IO[0]             | IO[3:0]              | IO[3:0]             |
| Data Input            | SI/IO[0]                               | IO[3:0]              | IO[3:0]              | IO[3:0]             |
| Data Output           | SO/IO[1]                               | IO[3:0]              | IO[3:0]              | IO[3:0]             |

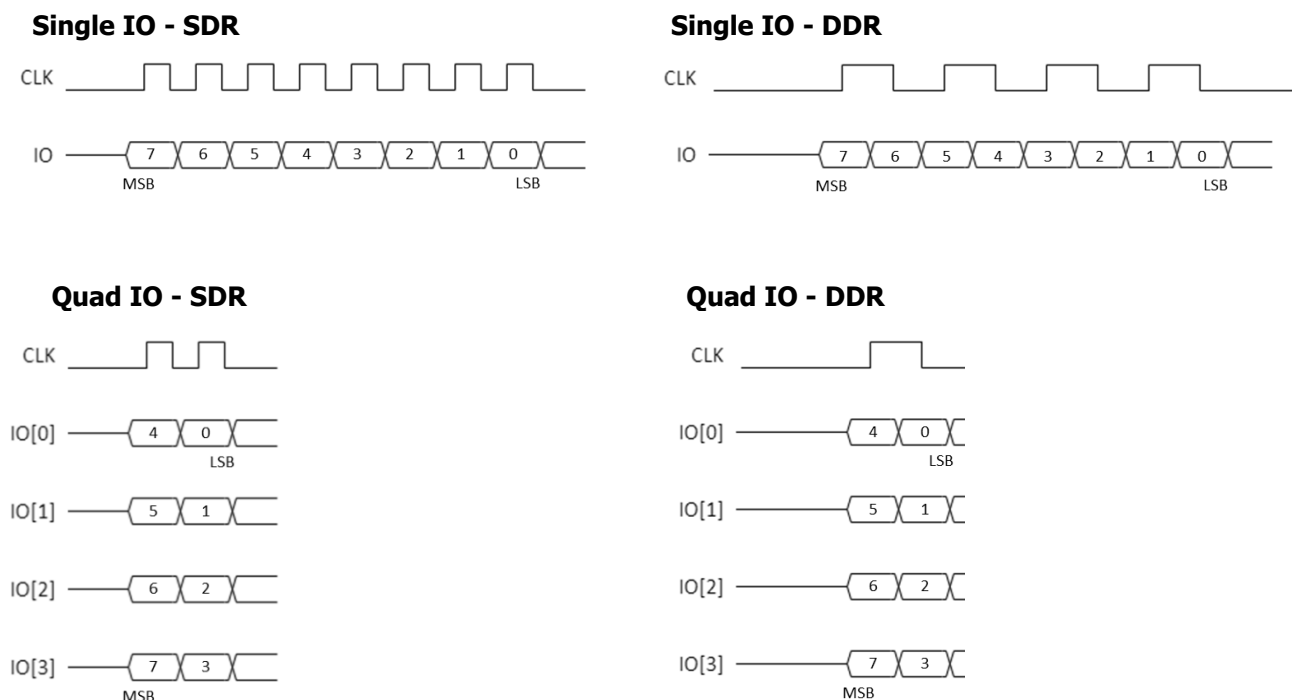
### Notes:

1. 1 or 4 : bit width, s: SDR, d: DDR

## 6.3 MSB/LSB Location

The most significant bit(MSB) is placed first at all commands, address and data.

**Figure 6: Location of MSB and LSB**



## 7. Device Operation

### 7.1 Instruction Command Set

Each instruction begins with an 8-bit command which selects the type of operation. The command can be used independently, or followed by address and data, or followed by data only. During XIP operation, the first 24 bits represent the read or write address. Avoid entering invalid command codes (except for the following instruction sets). The table below shows the instruction command table for each individual die.

**Table 21: Instruction Command Table**

| Instruction Command Set                      |      | Code | Command-Address-Data |          |     |                |            | Max. Frequency |
|----------------------------------------------|------|------|----------------------|----------|-----|----------------|------------|----------------|
| Command                                      | Name |      | Extended SPI         | Quad SPI | XIP | Latency Cycles | Data Bytes |                |
| Control Instructions                         |      |      |                      |          |     |                |            |                |
| No operation                                 | NOOP | 00h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Write Enable                                 | WREN | 06h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Write Disable                                | WRDI | 04h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Enable Quad SPI                              | QPIE | 38h  | 1s-0-0               | -        | -   | -              | -          | 150MHz         |
| Enable Extended SPI                          | SPIE | FFh  | -                    | 4s-0-0   | -   | -              | -          | 150MHz         |
| Enter Deep Power Down                        | DPDE | B9h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Exit Deep Power Down                         | DPDX | ABh  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Software Reset Enable                        | SRTE | 66h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Software Reset                               | SRST | 99h  | 1s-0-0               | 4s-0-0   | -   | -              | -          | 150MHz         |
| Read Register Instructions                   |      |      |                      |          |     |                |            |                |
| Read Status Register                         | RDSR | 05h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Configuration Register 1                | RDC1 | 35h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Configuration Register 2                | RDC2 | 3Fh  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Configuration Register 3                | RDC3 | 44h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Configuration Register 4                | RDC4 | 45h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Configuration Register 1-4              | RDCX | 46h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 4          | 150MHz         |
| Read Device ID                               | RDID | 9Fh  | 1s-0-1s              | 4s-0-4s  | -   | -              | 4          | 150MHz         |
| Read Unique ID                               | RUID | 4Ch  | 1s-0-1s              | 4s-0-4s  | -   | -              | 8          | 54MHz          |
| Read Serial Number Register                  | RDSN | C3h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 8          | 150MHz         |
| Read Augmented 512-byte Protection Register  | RDAP | 14h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Read Any Register - Address Based            | RDAR | 65h  | 1s-1s-1s             | 4s-4s-4s |     | O              | 1,4,8      | 150MHz         |
| Write Register Instructions                  |      |      |                      |          |     |                |            |                |
| Write Status Register                        | WRSR | 01h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Write Configuration Registers 1-4            | WRCX | 87h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 4          | 150MHz         |
| Write Serial Number Register                 | WRSN | C2h  | 1s-0-1s              | 4s-0-4s  | -   | -              | 8          | 150MHz         |
| Write Augmented 512-byte Protection Register | WRAP | 1Ah  | 1s-0-1s              | 4s-0-4s  | -   | -              | 1          | 150MHz         |
| Write Any Register - Address Based           | WRAR | 71h  | 1s-1s-1s             | 4s-4s-4s | -   | -              | 1,8        | 150MHz         |

| Instruction Command Set                         |      | Code | Command-Address-Data    |          |     |                |            | Max. Frequency |
|-------------------------------------------------|------|------|-------------------------|----------|-----|----------------|------------|----------------|
| Command                                         | Name |      | Extended SPI            | Quad SPI | XIP | Latency Cycles | Data Bytes |                |
| Read Memory Instructions                        |      |      |                         |          |     |                |            |                |
| Read Memory - SDR                               | READ | 03h  | 1s-1s-1s                | -        | -   | -              | 1→∞        | 54MHz          |
| Fast Read Memory - SDR                          | RDFT | 0Bh  | 1s-1s-1s                | 4s-4s-4s | O   | O              | 1→∞        | 150MHz         |
| Fast Read Memory - DDR                          | DRFR | 0Dh  | 1d-1d-1d                | 4s-4d-4d | O   | O              | 1→∞        | 75MHz          |
| Read Quad Output Memory - SDR                   | RDQO | 6Bh  | 1s-1s-4s <sup>(6)</sup> | 4s-4s-4s | O   | O              | 1→∞        | 150MHz         |
| Read Quad Output Memory - DDR                   | DRQO | 6Dh  | 1s-1d-4d <sup>(6)</sup> | 4s-4d-4d | O   | O              | 1→∞        | 75MHz          |
| Read Quad IO Memory - SDR                       | RDQI | EBh  | 1s-4s-4s <sup>(6)</sup> | 4s-4s-4s | O   | O              | 1→∞        | 150MHz         |
| Read Quad IO Memory - DDR                       | DRQI | EDh  | 1s-4d-4d                | 4s-4d-4d | O   | O              | 1→∞        | 75MHz          |
| Write Memory Instructions                       |      |      |                         |          |     |                |            |                |
| Write Memory - SDR                              | WRTE | 02h  | 1s-1s-1s                | 4s-4s-4s | -   | -              | 1→∞        | 150MHz         |
| Fast Write Memory - SDR                         | WRFT | DAh  | 1s-1s-1s                | 4s-4s-4s | O   | -              | 1→∞        | 150MHz         |
| Fast Write Memory - DDR                         | DRFW | DEh  | 1s-1d-1d                | 4s-4d-4d | O   | -              | 1→∞        | 75MHz          |
| Write Quad Input Memory - SDR                   | WQDI | 32h  | 1s-1s-4s <sup>(6)</sup> | 4s-4s-4s | O   | -              | 1→∞        | 150MHz         |
| Write Quad Input Memory - DDR                   | DWQI | 31h  | 1s-1d-4d <sup>(6)</sup> | 4s-4d-4d | O   | -              | 1→∞        | 75MHz          |
| Write Quad IO Memory - SDR                      | WQIO | D2h  | 1s-4s-4s <sup>(6)</sup> | 4s-4s-4s | O   | -              | 1→∞        | 150MHz         |
| Write Quad IO Memory - DDR                      | DWQO | D1h  | 1s-4d-4d                | 4s-4d-4d | O   | -              | 1→∞        | 75MHz          |
| Read/Write Augmented 512-Byte Area Instructions |      |      |                         |          |     |                |            |                |
| Read Augmented Area                             | RDAS | 4Bh  | 1s-1s-1s                | -        | -   | O              | 1→512      | 150MHz         |
| Write Augmented Area                            | WRAS | 42h  | 1s-1s-1s                | -        | -   | -              | 1→512      | 150MHz         |

### Notes:

- Cs-A(s/d)-D(s/d) format: C stands for Command input, A stands for Address input, D stands for either Data input or Output, 's' stands for SDR, 'd' stands for DDR.  
'0' in Cs-A(s/d)-D(s/d) format indicates that no byte is required.  
'-' indicates 'not supported' or 'not required'.
- Extended SPI mode is enabled after power-on, software reset or JEDEC reset.
- Read Register operations do not wrap data. Reading beyond the specified number of bytes will yield indeterminate data.
- Write Enable (WREN) should be implemented in advance of Write Register Instruction set regardless of CR4[1:0] setting.  
The WREN prerequisite for write operation of memory and augmented area is described in Configuration Register 4.
- Latency is configurable through Configuration Register 2 (CR2[3:0]) and frequency dependent.  
Required latency is described in Configuration Register 2.
- The frequency of 1s-1s-4s and 1s-4s-4s is limited to 108MHz.  
The frequency of 1s-1d-4d is limited to 54MHz.

## 7.2 RESET Operations

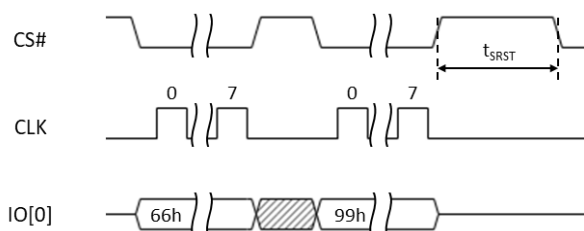
The device supports the software reset and JEDEC reset functions. The device may be reset in software by the Reset Enable and Software Reset instructions or JEDEC reset. Extended SPI mode is enabled after software reset or JEDEC reset.

### 7.2.1 Software Reset

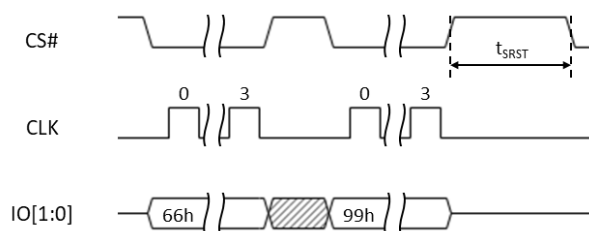
To reset the device in software, the Reset Enable command is issued, followed by the Software Reset command. The device then enters a power-on reset condition. The CS# High time( $t_{SRST}$ ) must be observed between commands.

**Figure 7: Software Reset Timing**

#### Extended SPI

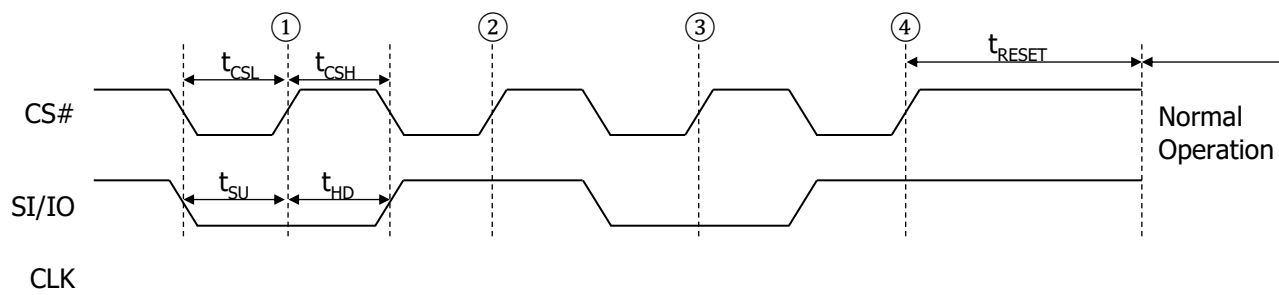


#### Quad SPI



### 7.2.2 JEDEC Reset

**Figure 8: JEDEC Reset Timing**



**Table 22: JEDEC Reset Timing**

| Parameter                       | Symbol      | Min. | Max. | Units   |
|---------------------------------|-------------|------|------|---------|
| CS# Low Time                    | $t_{CSL}$   | 0.5  | -    | $\mu s$ |
| CS# High Time                   | $t_{CSH}$   | 0.5  | -    | $\mu s$ |
| SI/IO[0] Setup Time (w.r.t CS#) | $t_{SU}$    | 5.0  | -    | ns      |
| SI/IO[0] Hold Time (w.r.t CS#)  | $t_{HD}$    | 5.0  | -    | ns      |
| JEDEC Hardware Reset            | $t_{RESET}$ | -    | 2.0  | ms      |

### 7.3 WRITE ENABLE/DISABLE Operations

To initiate a command for each die, CS# must be driven Low and held Low until the eighth bit of the command code is latched in, then driven High. For Extended SPI and Quad SPI protocols respectively, the command code is input on IO[0] and IO[3:0].

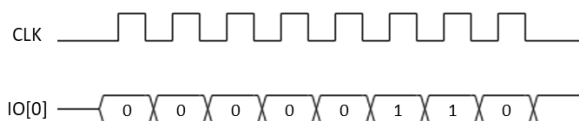
A Write Enable command (WREN) is needed to set the WREN bit prior to Write Register Instruction regardless of CR4[1:0] setting.

The WREN prerequisite for write operation of memory and augmented area is described in Configuration Register 4.

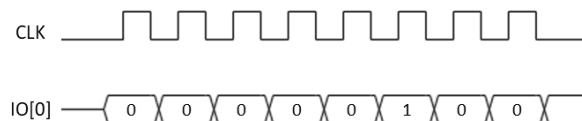
**Figure 9: WRITE Enable/Disable Timing**

#### WRITE ENABLE (06h)

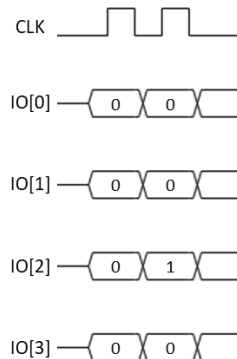
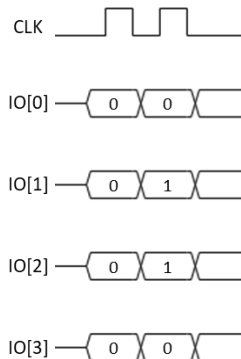
##### Extended SPI



#### WRITE DISABLE (04h)



##### Quad SPI

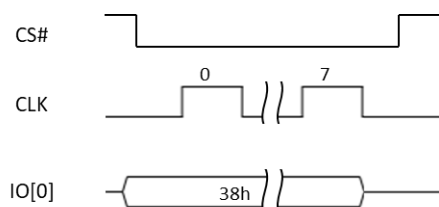


## 7.4 Enable Extended, Quad SPI mode and No Operation

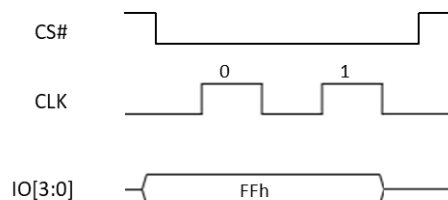
To initiate a command for each die, CS# is driven Low and held Low until the eighth bit of the command code is latched in, then driven High. For Extended SPI and Quad SPI protocols respectively, the command code is input on IO[0] and IO[3:0]. When Quad SPI is enabled, CR2[6] bit of the Configuration Register 2 is set to '1', otherwise, CR2[6] bit is reset to '0'.

**Figure 10: Enable Extended SPI or Quad SPI mode**

### Extended SPI → Quad SPI



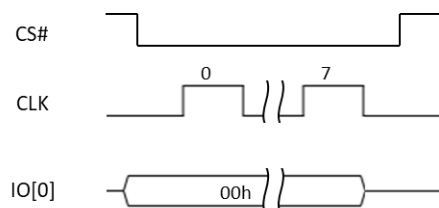
### Quad SPI → Extended SPI



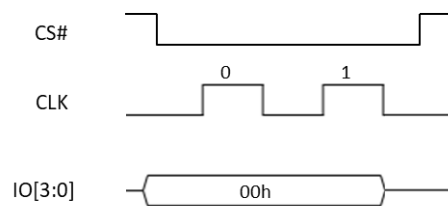
If a no-operation command (00h) is entered, the device will not perform any action. For example, in the S3H6408R1M device, if you want to operate only one of the two dies, enter the 00h command to the other die.

**Figure 11: No operation**

### Extended SPI



### Quad SPI



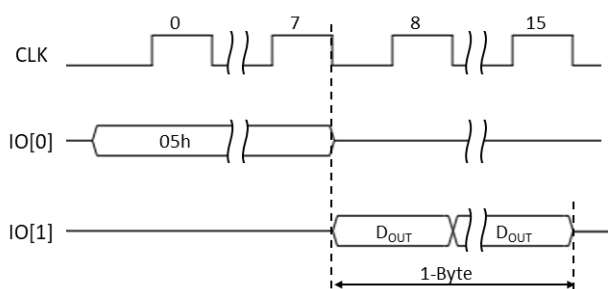
## 7.5 Register Operation

### 7.5.1. Read Register Operations

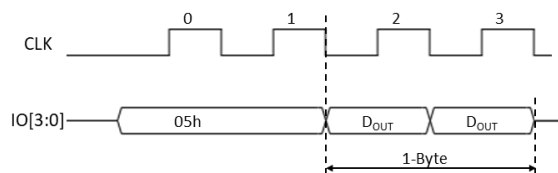
To initiate register read operations, CS# is driven Low and the command code is input, followed by input of the address bytes if required. The operation is terminated by driving CS# High, and the output goes to High-Z.

**Figure 12: Read Status Register Timing**

#### Extended SPI

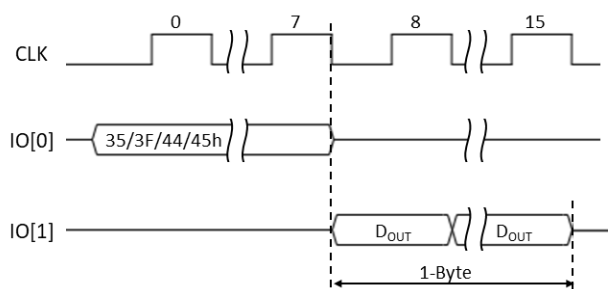


#### Quad SPI

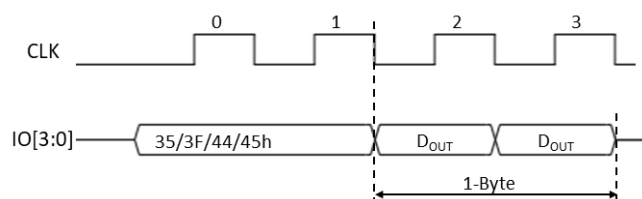


**Figure 13: Read Configuration Register 1, 2, 3 or 4 Timing**

#### Extended SPI

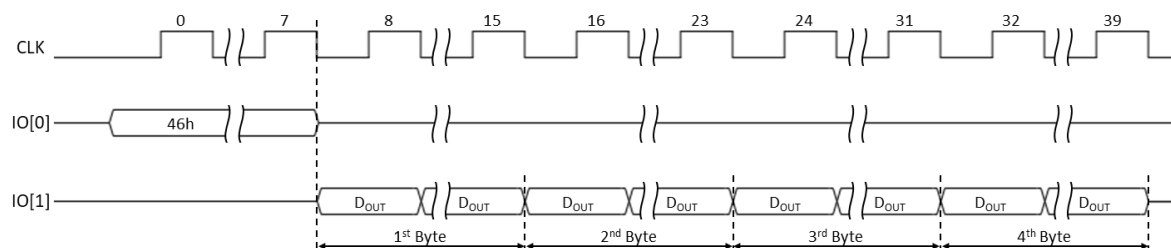


#### Quad SPI

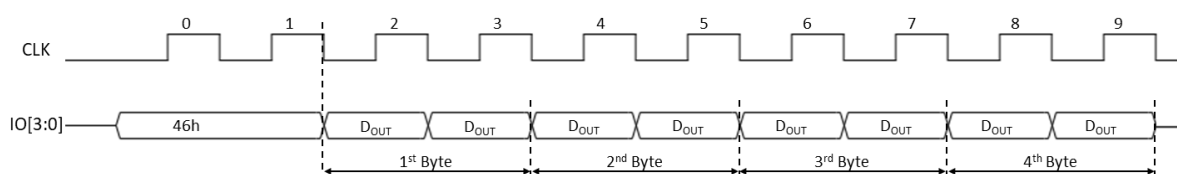


**Figure 14: Read Configuration Register 1-4 Timing**

### Extended SPI



### Quad SPI

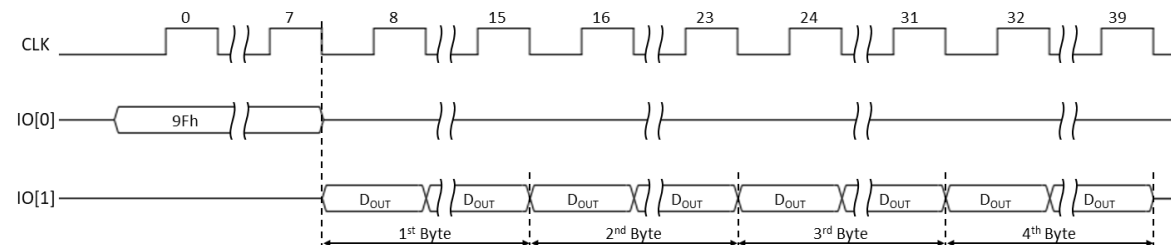


### Notes:

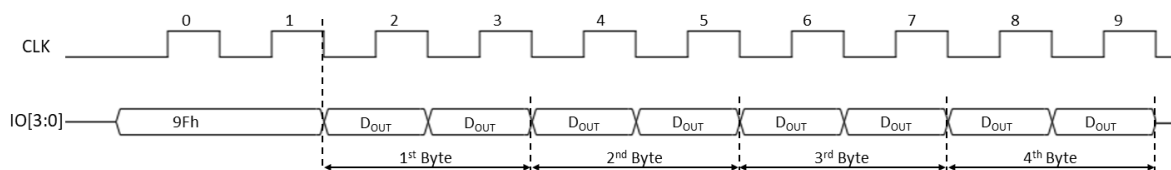
1. 1<sup>st</sup> Byte: CR1[7:0], 2<sup>nd</sup> Byte: CR2[7:0], 3<sup>rd</sup> Byte: CR3[7:0], 4<sup>th</sup> Byte: CR4[7:0],

**Figure 15: Read Device ID Timing**

### Extended SPI

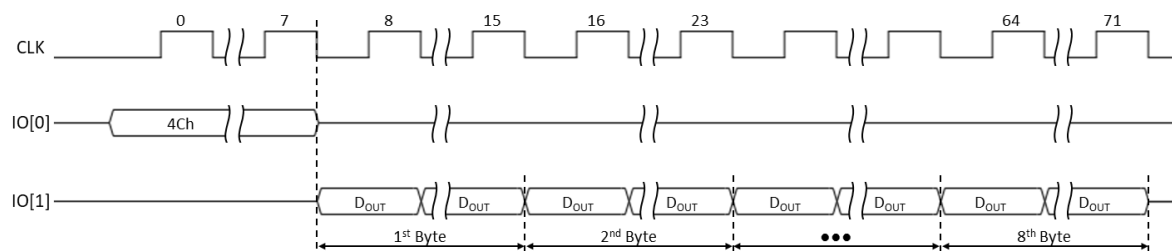


### Quad SPI

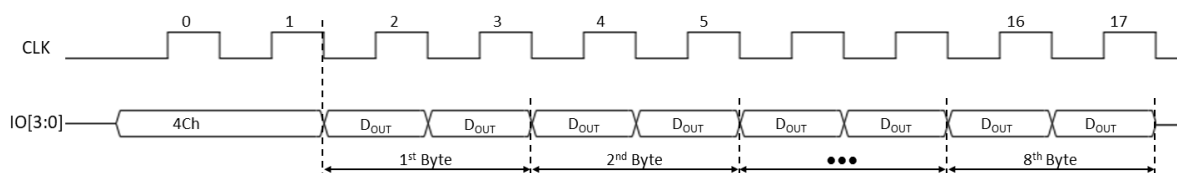


**Figure 16: Read Unique ID Timing**

### Extended SPI

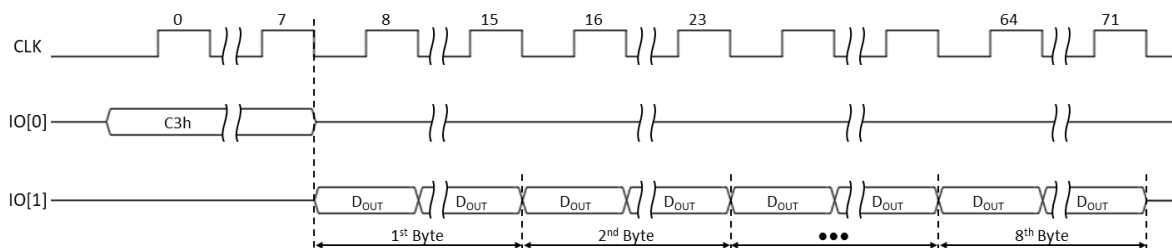


### Quad SPI

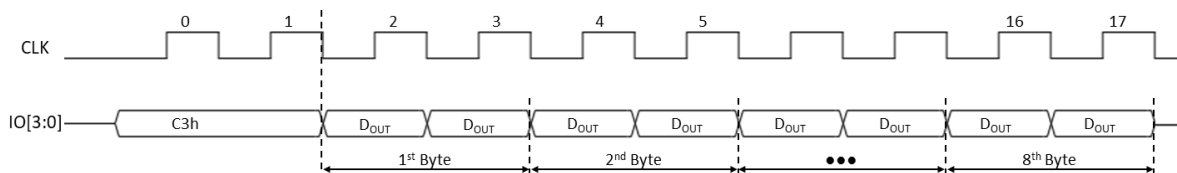


**Figure 17: Read Serial Number Register Timing**

### Extended SPI

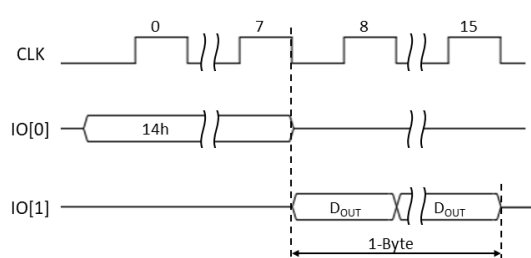


### Quad SPI

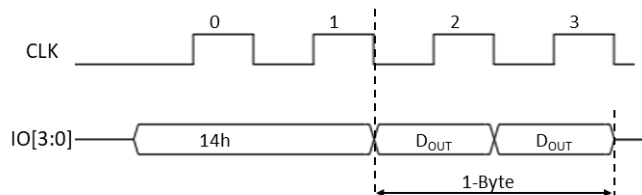


**Figure 18: Read Augmented 512-byte Protection Register Timing**

### Extended SPI

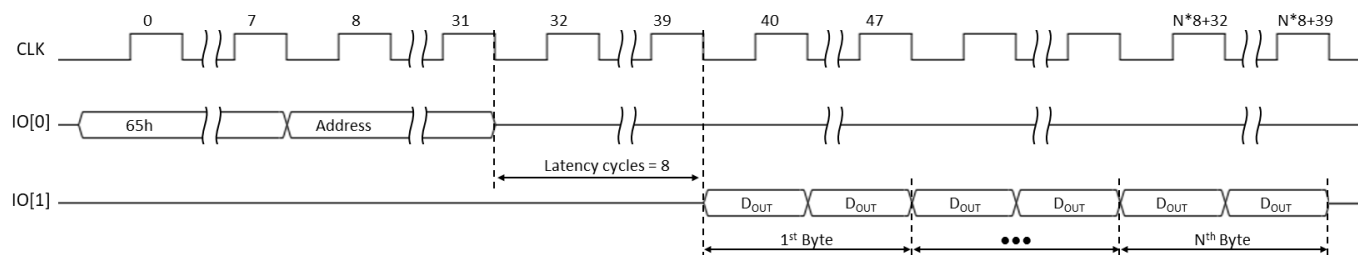


### Quad SPI

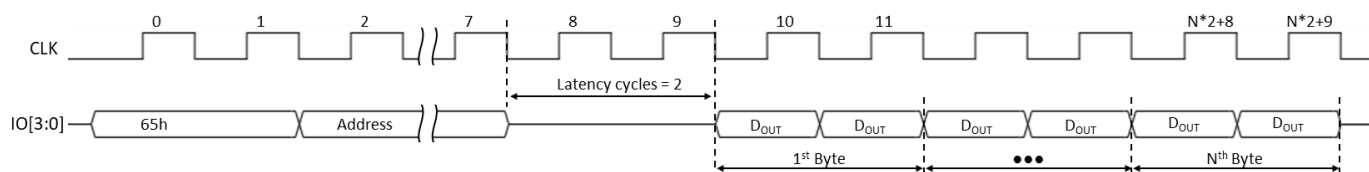


**Figure 19: Read Any Register Timing**

### Extended SPI



### Quad SPI



#### Notes:

1. The latency cycles of Read Any Register instruction (65h) are 8 in Extended SPI or 2 in Quad SPI, regardless of Read latency Selection Bits CR2[3:0].
2. N can be 1, 4, or 8. See the table 5: Register Address Map.

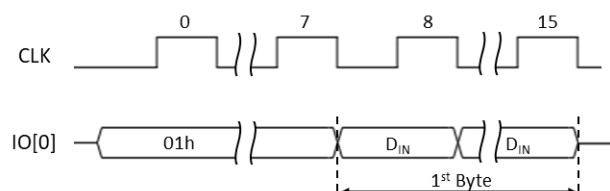
### 7.5.2. WRITE REGISTER Operations

Before a Write Register command is initiated, Status Register or Configuration Register should be set Writable (See Table 7: Write Protection Modes).

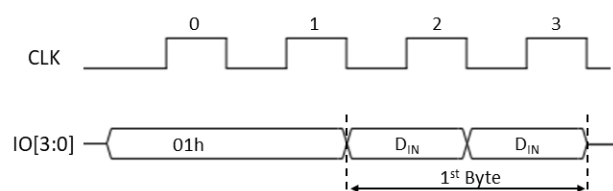
To initiate register write operations, CS# is driven Low and the command code is input, followed by input of the address bytes if required, and followed by the input data. The operation is terminated by driving CS# High.

**Figure 20: Write Status Register Timing**

#### Extended SPI

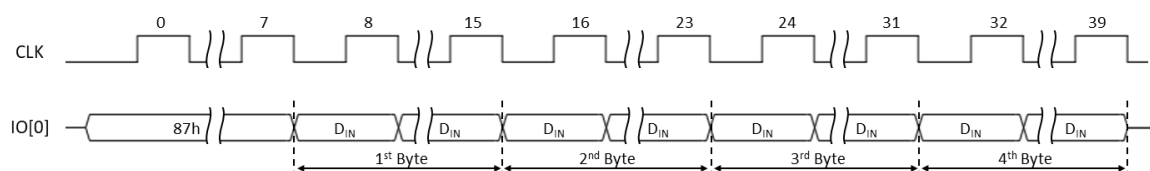


#### Quad SPI

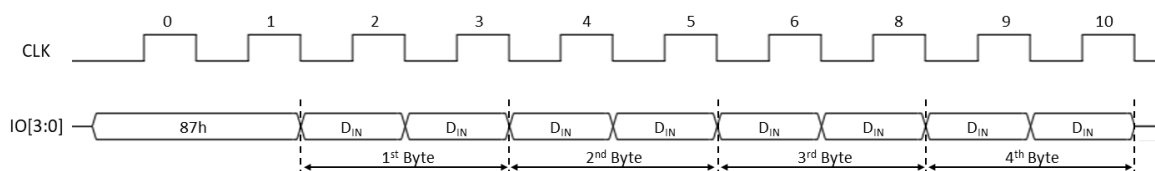


**Figure 21: Write Configuration Register 1-4 Timing**

#### Extended SPI



#### Quad SPI

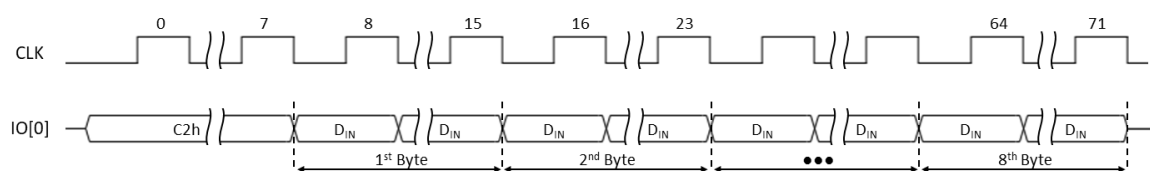


#### Notes:

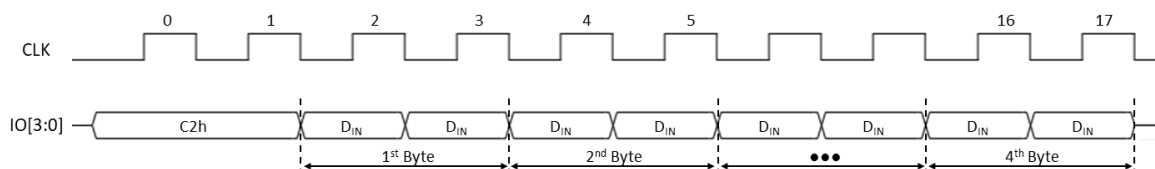
1. 1<sup>st</sup> Byte: CR1[7:0], 2<sup>nd</sup> Byte: CR2[7:0], 3<sup>rd</sup> Byte: CR3[7:0], 4<sup>th</sup> Byte: CR4[7:0],

**Figure 22: Write Serial Number Register Timing**

#### Extended SPI

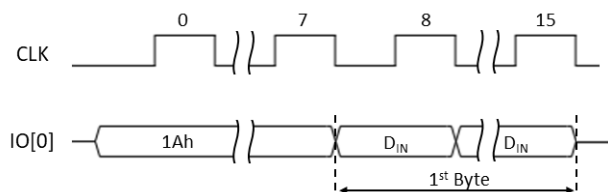


#### Quad SPI

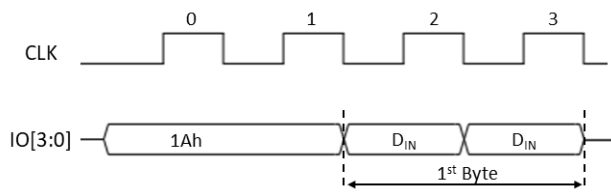


**Figure 23: Write Augmented 512-byte Protection Register Timing**

### Extended SPI

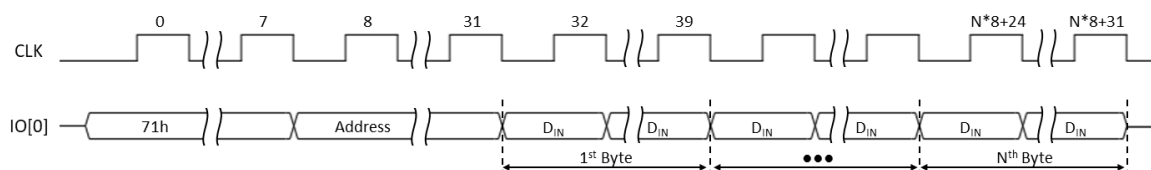


### Quad SPI

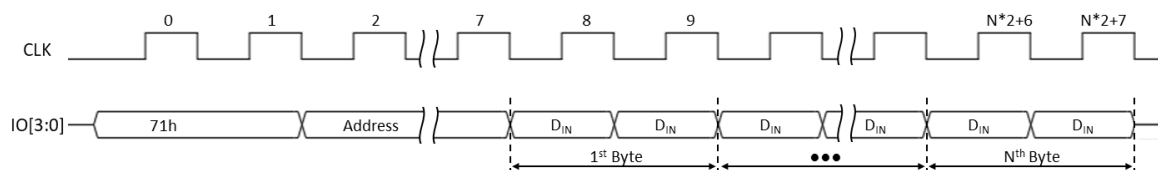


**Figure 24: Write Any Register Timing**

### Extended SPI



### Quad SPI



### Notes:

1. N can be 1 or 8 depending on the address. See the table 5 - Register Address Map.

## 7.6 Memory Operation

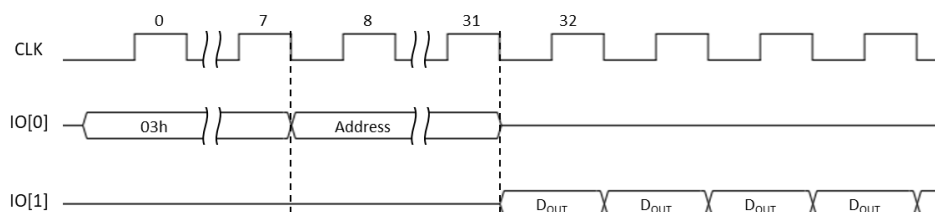
To initiate memory read operation, CS# is driven Low and the command code is input, followed by input of the address bytes. The operation is terminated by driving CS# High at any time during data output.

### 7.6.1 READ MEMORY Operations

**Figure 25: Read Memory Timing**

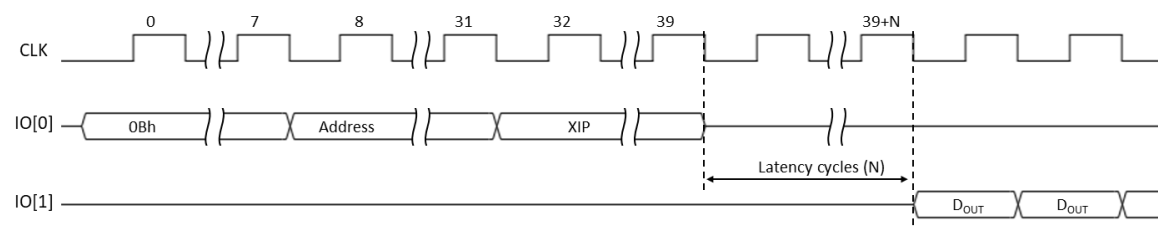
#### 1) 1s-1s-1s transaction

##### Extended SPI: Read Memory (03h)



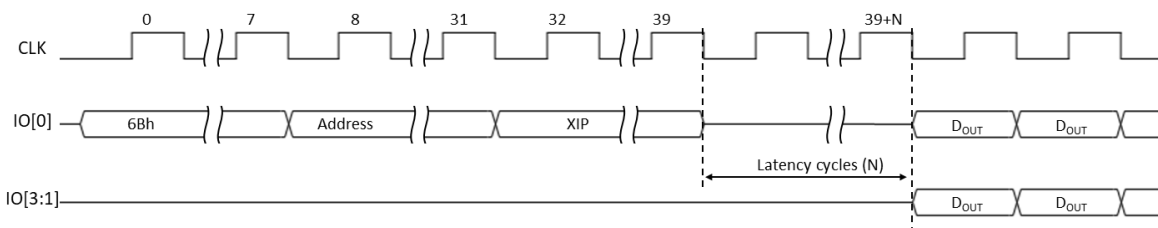
#### 2) 1s-1s-1s transaction

##### Extended SPI: Fast Read Memory (0Bh)



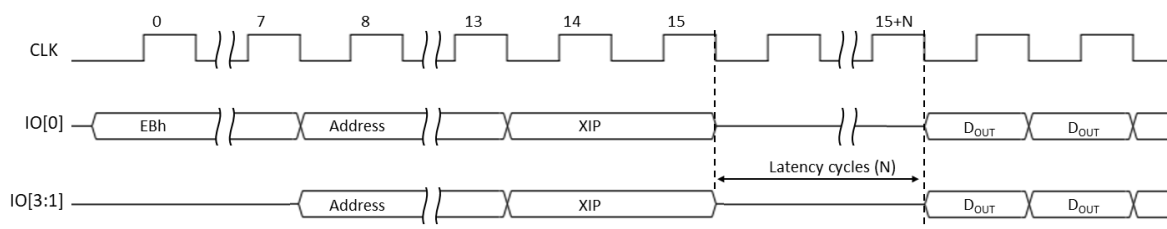
#### 3) 1s-1s-4s transaction

##### Extended SPI: Read Quad Output Memory (6Bh)



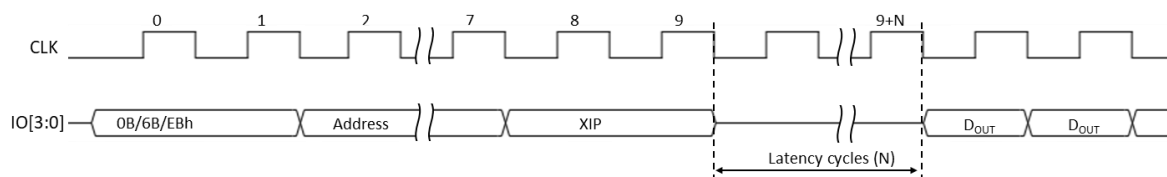
#### 4) 1s-4s-4s transaction

##### Extended SPI: Read Quad IO Memory (EBh)



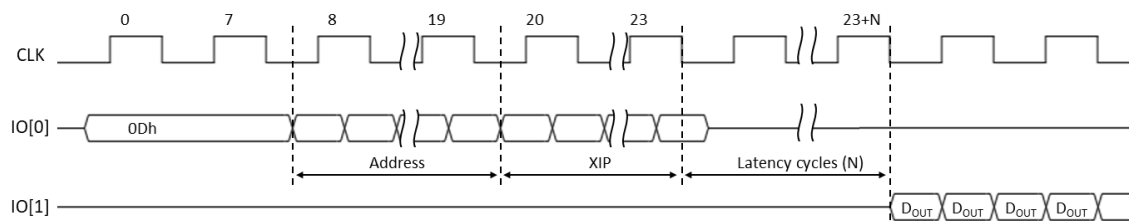
### 5) 4s-4s-4s transaction

**Quad SPI: Fast Read Memory (0Bh), Read Quad Output Memory (6Bh), Read Quad I/O Memory (EBh)**



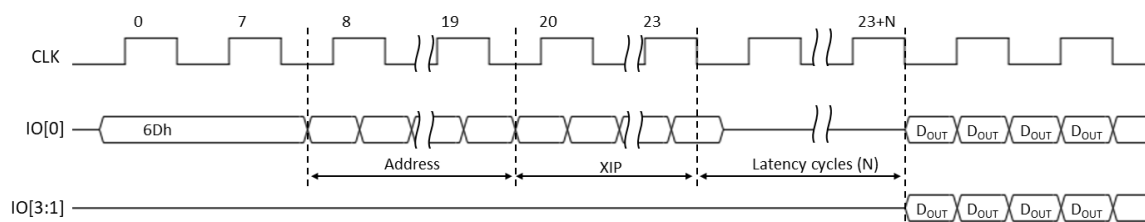
### 6) 1s-1d-1d transaction

**Extended SPI: Fast Read Memory-DDR (0Dh)**



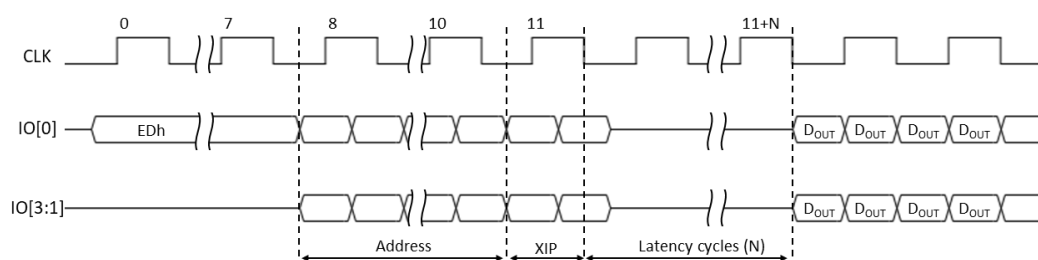
### 7) 1s-1d-4d transaction

**Extended SPI: Read Quad Output Memory-DDR (6Dh)**



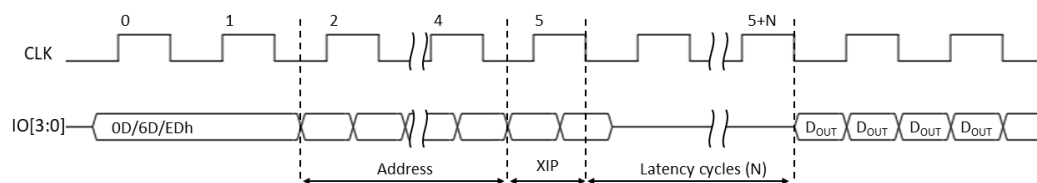
### 8) 1s-4d-4d transaction

**Extended SPI: Read Quad IO Memory-DDR (EDh)**



### 9) 4s-4d-4d transaction

**QUAD SPI: Fast Read Memory-DDR (0Dh), Read Quad Output Memory-DDR (6Dh), Read Quad IO Memory-DDR (EDh)**



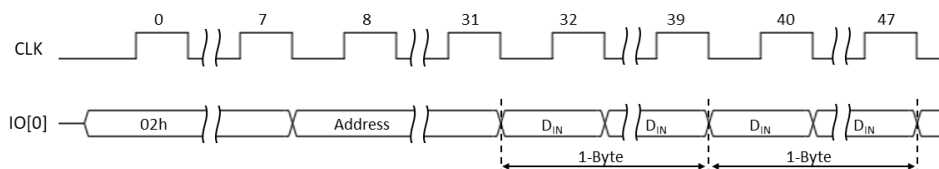
### 7.6.2 Write Memory Operations

To initiate memory write operation, CS# is driven Low and the command code is input, followed by input of the address and data. The operation is terminated by driving CS# High at any time during data input. The WREN prerequisite for write operation of memory is described in Configuration Register 4.

**Figure 26: Write Memory Timing**

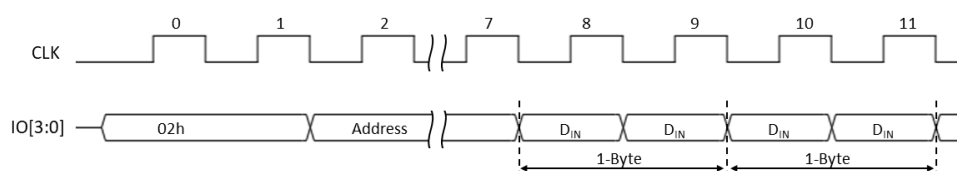
#### 1) 1s-1s-1s transaction

##### Extended SPI: Write Memory (02h)



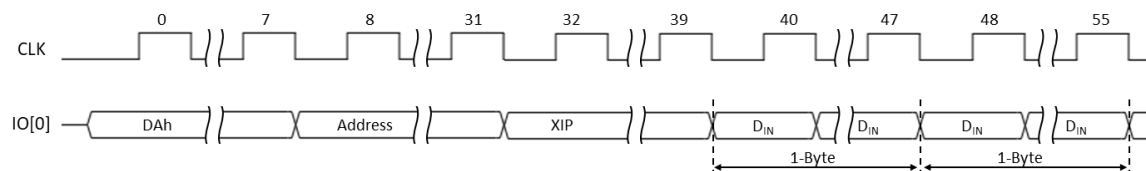
#### 2) 4s-4s-4s transaction

##### Quad SPI: Write Memory (02h)



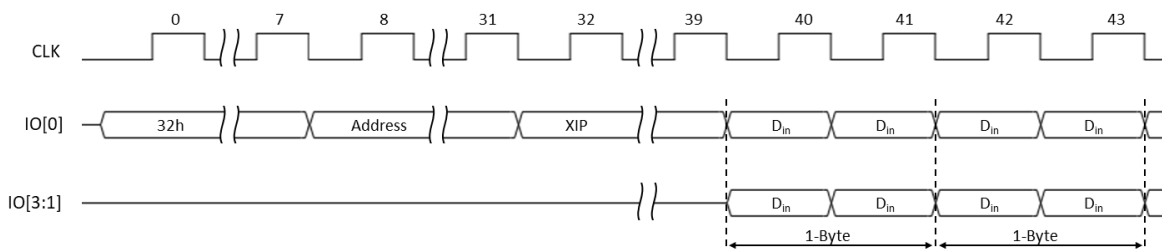
#### 3) 1s-1s-1s transaction with XIP

##### Extended SPI: Fast Write Memory (DAh)



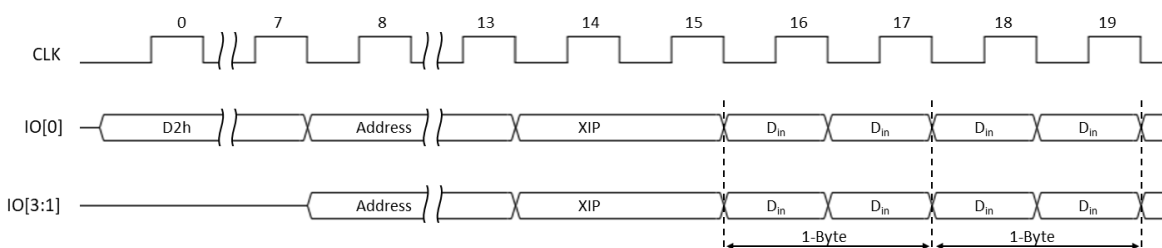
#### 4) 1s-1s-4s transaction with XIP

##### Extended SPI: Write Quad Input Memory (32h)



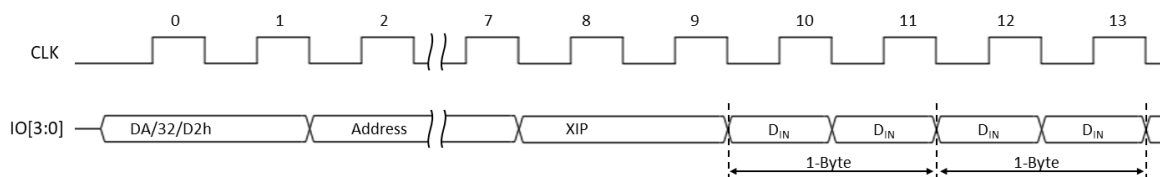
#### 5) 1s-4s-4s transaction with XIP

##### Extended SPI: Write Quad IO Memory (D2h)



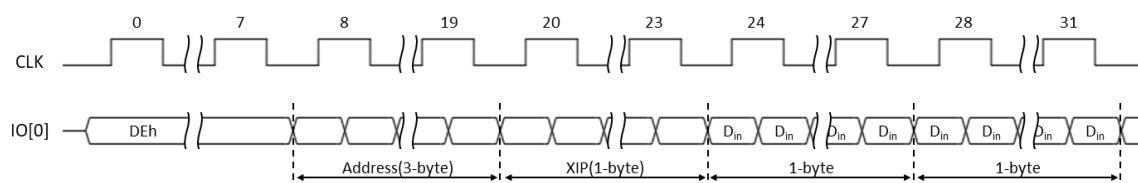
### 6) 4s-4s-4s transaction with XIP

Quad SPI: Fast Write Memory (DAh), Write Quad Input Memory (32h), Write Quad IO Memory (D2h)



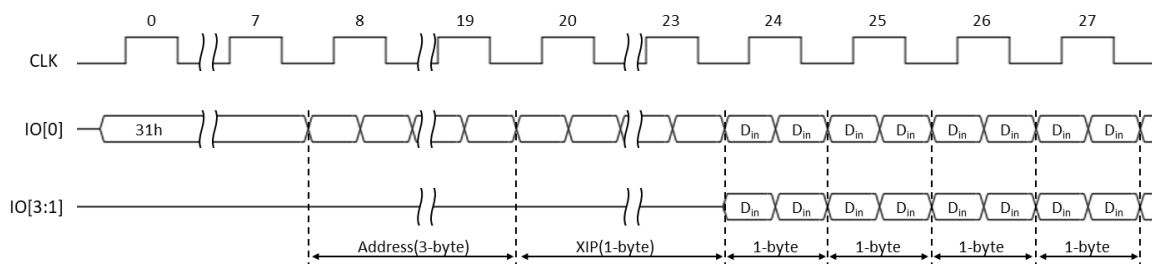
### 7) 1s-1d-1d transaction with XIP

Extended SPI: Fast Write Memory -DDR (DEh)



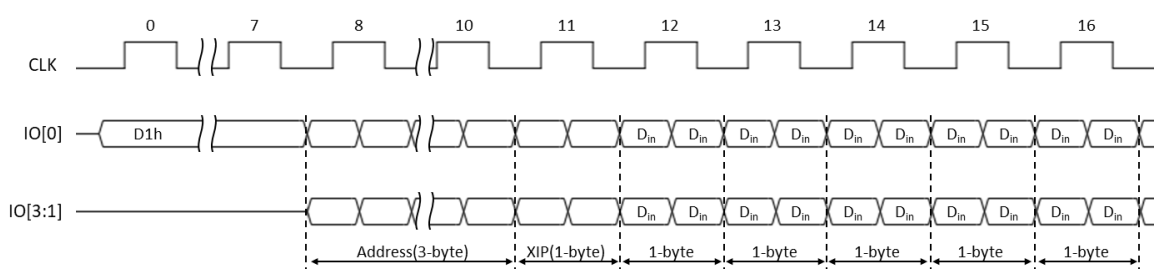
### 8) 1s-1d-4d transaction with XIP

Extended SPI: Write Quad Input Memory -DDR (31h)



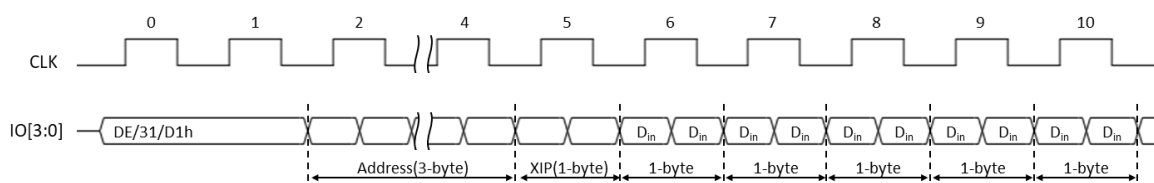
### 9) 1s-4d-4d transaction with XIP

Extended SPI: Write Quad IO Memory -DDR (D1h)



### 10) 4s-4d-4d transaction with XIP

Quad SPI: Fast Write Memory -DDR(DEh), Write Quad Input Memory -DDR(31h), Write Quad IO Memory -DDR (D1h)



### 7.6.3 XIP Operations

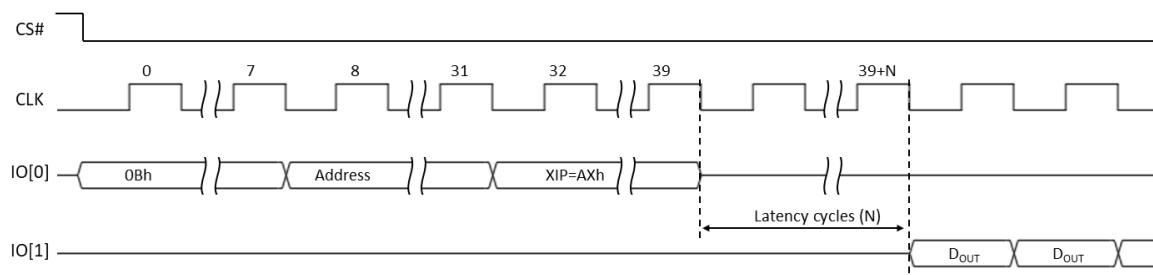
The device offers XIP (execute in place) mode for both read and write operations.

XIP allows a series of read or write operation without loading individual read or write command for each instruction, which results in reduced random access time. XIP is enabled by entering byte AXh and disabled by entering any byte not equal to AXh (X=Don't Care). These respective bytes must be entered following the address bits. Read operation with XIP needs extra read latency cycles before data output. The read latency cycles are specified in Table 12.

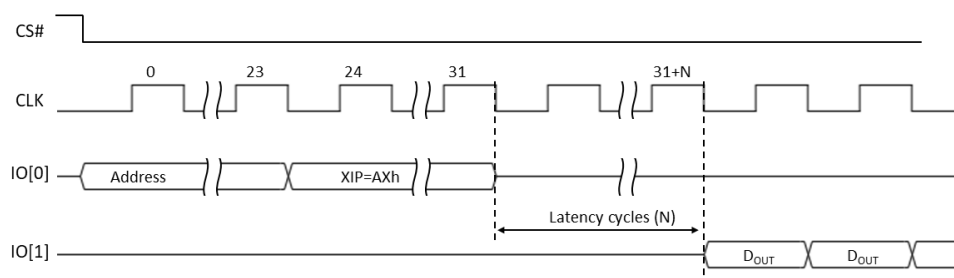
**Figure 27: Read XIP Timing**

#### 1) 1s-1s-1s transaction, Extended SPI, Read operation

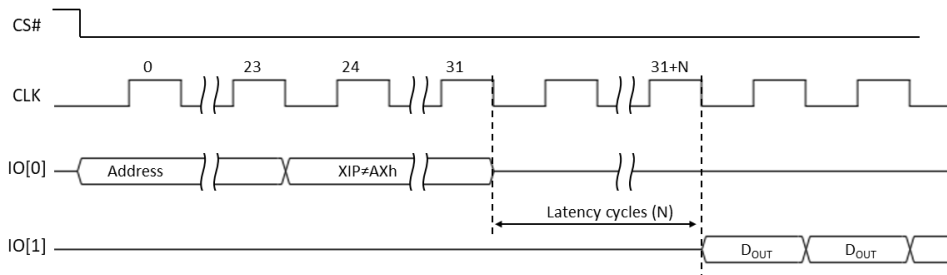
##### - Enabling XIP



##### - Continuous XIP

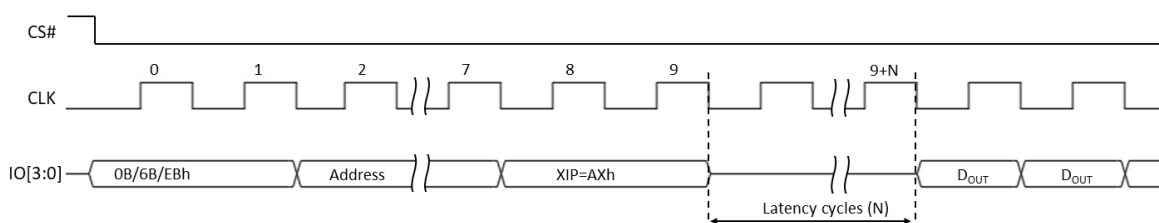


##### - Terminating XIP

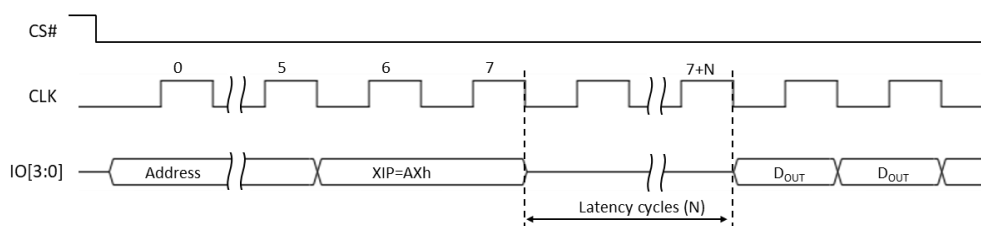


#### 2) 4s-4s-4s transaction, Quad SPI, Read operation

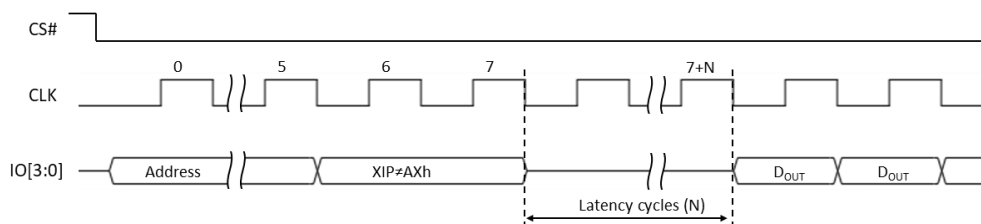
##### - Enabling XIP



### - Continuous XIP

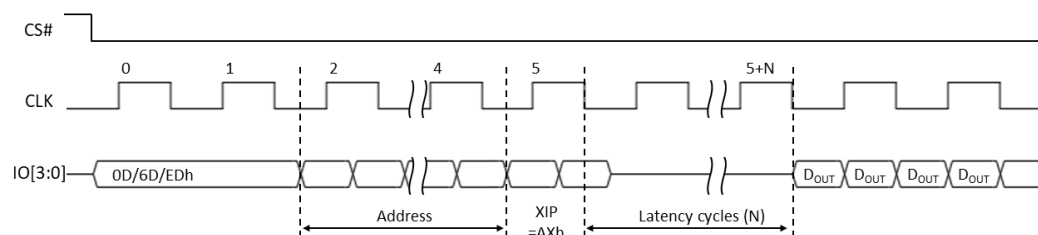


### - Terminating XIP

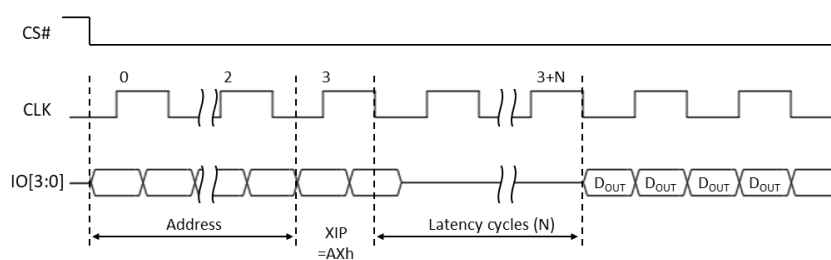


### 3)4s-4d-4d transaction, Quad SPI, Read operation

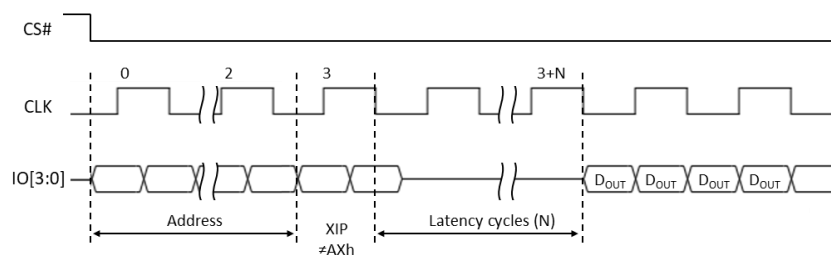
#### - Enabling XIP



### - Continuous XIP



### - Terminating XIP



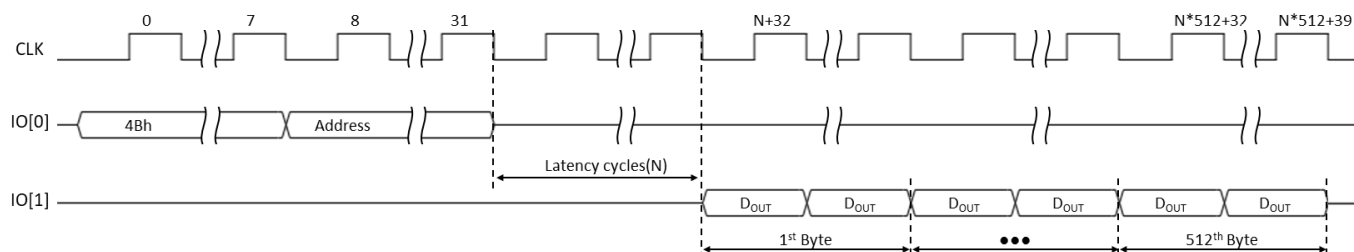
Other transactions or Write XIP operations are similar.

## 7.7 Augmented Area Operation

To initiate read operation for augmented area, CS# is driven Low and the command code is input, followed by input of the address bytes. The operation is terminated by driving CS# High at any time during data output.

**Figure 28: Read Augmented 512-byte Area Timing**

### 1s-1s-1s transaction



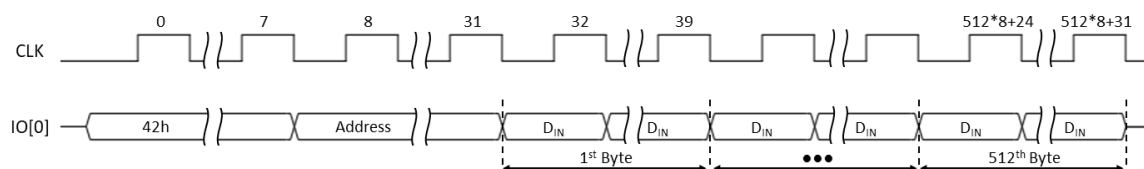
### Notes:

1. Latency cycles for Read Augmented 512-byte Area are configurable through Configuration Register 2 (CR2[3:0]).

To initiate write operation for augmented area, CS# is driven Low and the command code is input, followed by input of the address and data. The operation is terminated by driving CS# High at any time during data input. The WREN prerequisite for write operation of augmented area is described in Configuration Register 4.

**Figure 29: Write Augmented 512-byte Area Timing**

### 1s-1s-1s transaction



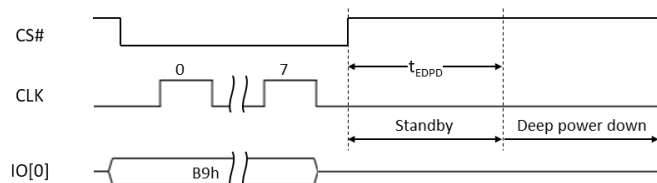
## 7.8 Deep Power-down Operation

The device provides Deep Power Down mode. This mode reduces current consumption from  $I_{SB}$  to  $I_{DPD}$ . To enter the deep power down mode, CS# is driven Low, followed by Enter Deep Power Down (B9h) command, CS# is driven High after the eighth bit of the command code has been latched in.

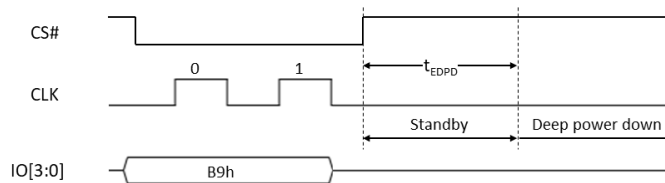
After CS# is driven High, it requires a delay of  $t_{EDPD}$  before the supply current is reduced to  $I_{DPD}$  and the Deep Power Down mode is entered. The command can be issued in Extended SPI or Quad SPI modes.

### Deep Power-down Enter

#### Extended SPI



#### Quad SPI

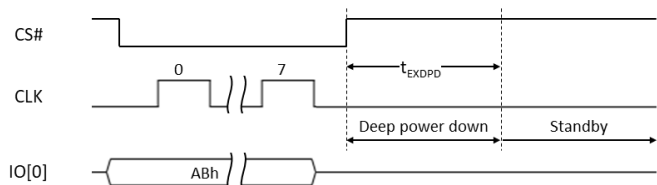


There are two ways to exit deep power down mode:

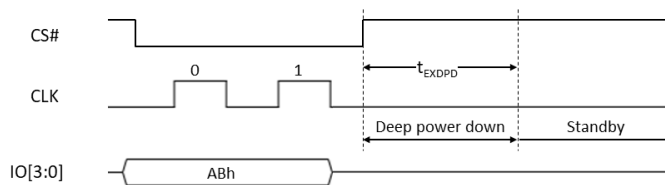
1. Driving CS# Low is followed with Exit Deep Power Down (ABh) command. CS# must be driven High after the eighth bit of the command code is latched in.
2. Toggling CS# with a pulse width of  $t_{CSDPD}$  while CLK and I/Os are Don't Care state. During waking up from deep power down, I/Os remain to be in High-Z.

### Deep Power-down Exit

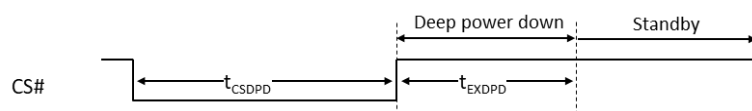
#### Extended SPI



#### Quad SPI



### Toggling CS#



It requires a delay of  $t_{EXDPD}$  before the device can fully exit the deep power down mode and enter standby mode.

Status of all non-volatile bits in registers and operation mode (Extended or Quad SPI mode) remains unchanged when the device enters or exits the deep power down mode. The command can be issued in Extended SPI or Quad SPI mode.

## 8. Electrical Specifications

### 8.1 Absolute Maximum Ratings

Stresses greater than those listed may cause permanent damage to the device. This is a stress rating only. Exposure to maximum rating for extended periods may adversely affect reliability.

**Table 23: Absolute Maximum Ratings**

| Parameter                             | Min.                                                                                                                              | Max. | Units |
|---------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------|------|-------|
| Voltage on Vcc Supply Relative to VSS | -0.5                                                                                                                              | 2.35 | V     |
| Voltage on Any Pin relative to VSS    | -0.5                                                                                                                              | 2.35 | V     |
| Storage Temperature                   | -55                                                                                                                               | 150  | °C    |
| Operating Ambient Temperature         | -40                                                                                                                               | 85   | °C    |
| ESD HBM (Human Body Model)            | ≥  2000 V                                                                                                                         |      | V     |
| ESD CDM (Charged Device Model)        | ≥  500 V                                                                                                                          |      | V     |
| Package Process Condition             | JEDEC J-STD-020 reflow profiles<br>- Peak temperature ≤ 260°C<br>- The time above 255°C ≤ 30 seconds<br>- Reflow cycles ≤ 3 times |      |       |

### 8.2 Endurance, Retention and Magnetic Immunity

**Table 24: Write Endurance, Retention and Magnetic Immunity**

| Parameter                           | Conditions | Min.             | Max.   | Units  |
|-------------------------------------|------------|------------------|--------|--------|
| Write Endurance                     | -25°C      | 10 <sup>14</sup> | -      | cycles |
| Data Retention                      | 85°C       | 20               | -      | years  |
| Magnetic Field During Write or Read | -          | -                | 24,000 | A/m    |

## 8.3 Recommended Operating Conditions

**Table 25: Recommended Operating Conditions**

| Parameter / Condition |            | Min. | Typ. | Max. | Units |
|-----------------------|------------|------|------|------|-------|
| Operating Temperature | Industrial | -40  | 25   | 85   | °C    |
| Vcc Supply Voltage    |            | 1.71 | 1.8  | 1.98 | V     |
| Vss Supply Voltage    |            | 0.0  | 0.0  | 0.0  | V     |

## 8.4 Pin Capacitance

**Table 26: Pin Capacitance**

| Parameter                    | Conditions                                   | Typ. | Max. | Units |
|------------------------------|----------------------------------------------|------|------|-------|
| Input Pin Capacitance        | TEMP = 25°C; f = 1 MHz; V <sub>IN</sub> = 0V | -    | 6    | pF    |
| Input/Output Pin Capacitance | TEMP = 25°C; f = 1 MHz; V <sub>IO</sub> = 0V | -    | 10   | pF    |

**Notes:**

1. Capacitance is sampled and not 100% tested

## 8.5 AC Test Condition

**Table 27: AC Test Conditions**

| Parameter                                  | Value                    |
|--------------------------------------------|--------------------------|
| Input pulse levels                         | 0.0V to Vcc              |
| Input rise and fall times                  | 1ns/1V                   |
| Input and output measurement timing levels | Vcc/2                    |
| Output Load                                | C <sub>Load</sub> = 12pF |

## 8.6 DC Characteristics

**Table 28: DC Characteristics**

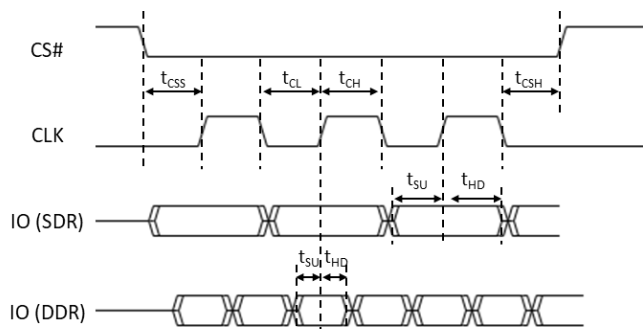
| Parameter                 | Symbol          | Test Conditions                                                     | 1.71V~1.98V                  |      |                     | Units   |
|---------------------------|-----------------|---------------------------------------------------------------------|------------------------------|------|---------------------|---------|
|                           |                 |                                                                     | Min.                         | Typ. | Max.                |         |
| Input Leakage Current     | $I_{LI}$        | $V_{IN} = 0$ to $V_{CC}$ (max)                                      | -2                           | -    | 2                   | $\mu A$ |
| Output Leakage Current    | $I_{LO}$        | $V_{OUT} = 0$ to $V_{CC}$ (max)                                     | -2                           | -    | 2                   | $\mu A$ |
| Read Current (1-1-1)      | $I_{CCR}$       | SDR=133MHz, DDR=66MHz<br>CS# or CS1# and CS2# = 0,<br>$I_{OUT}=0mA$ | -                            | 9    | 13                  | mA      |
| Read Current (4-4-4)      | $I_{CCR}$       |                                                                     | -                            | 16   | 24                  | mA      |
| Read Current (1-1-1)      | $I_{CCR}$       | SDR=150MHz, DDR=75MHz<br>CS# or CS1# and CS2# = 0,<br>$I_{OUT}=0mA$ | -                            | 11   | 17                  | mA      |
| Read Current (4-4-4)      | $I_{CCR}$       |                                                                     | -                            | 18   | 27                  | mA      |
| Write Current (1-1-1)     | $I_{CCW}$       | SDR=133MHz, DDR=66MHz<br>CS# or CS1# and CS2# = 0,<br>$I_{OUT}=0mA$ | -                            | 15   | 20                  | mA      |
| Write Current (4-4-4)     | $I_{CCW}$       |                                                                     | -                            | 43   | 56                  | mA      |
| Write Current (1-1-1)     | $I_{CCW}$       | SDR=150MHz, DDR=75MHz<br>CS# or CS1# and CS2# = 0,<br>$I_{OUT}=0mA$ | -                            | 16   | 21                  | mA      |
| Write Current (4-4-4)     | $I_{CCW}$       |                                                                     | -                            | 48   | 63                  | mA      |
| Standby Current           | $I_{SB}$        | CLK=0 or CLK1 and CLK2=0<br>CS# or CS1# and CS#=Vcc,<br>I/O=0/Vcc   | -                            | 1.2  | 1.8                 | mA      |
| Deep Power Down Current   | $I_{DPD}$       | CLK=0 or CLK1 and CLK2=0<br>CS# or CS1# and CS#=Vcc,<br>I/O=0/Vcc   | -                            | 120  | 580                 | $\mu A$ |
| Input High Voltage        | $V_{IH}$        | -                                                                   | $0.7 \times V_{CC}$          | -    | $V_{CC}+0.3$        | V       |
| Input Low Voltage         | $V_{IL}$        | -                                                                   | -0.3                         | -    | $0.3 \times V_{CC}$ | V       |
| Output High Voltage Level | $V_{OH}$        | $I_{OH} = -1mA$                                                     | 1.4                          | -    | -                   | V       |
| Output Low Voltage Level  | $V_{OL}$        | $I_{OL} = 2mA$                                                      | -                            | -    | 0.4                 | V       |
| Reset Current             | $I_{RST}^{(1)}$ | -                                                                   | About 135mA for around 1.1ms |      |                     | -       |

1. Reset Current includes the current of power-up, software reset, or JEDEC reset.  
This parameter is guaranteed by characterization: not tested in production.

## 8.7 AC Timing Characteristics

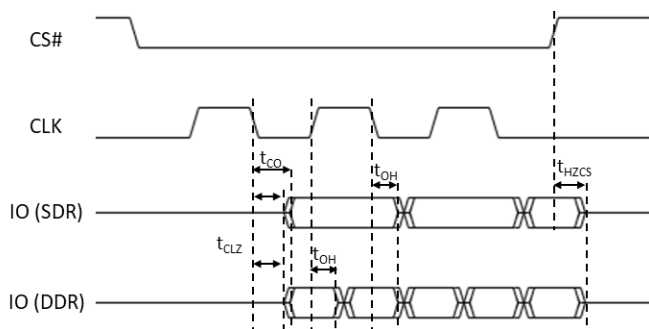
### 8.7.1 Synchronous Input Timing

**Figure 30: Synchronous Input Timing (SDR/DDR)**



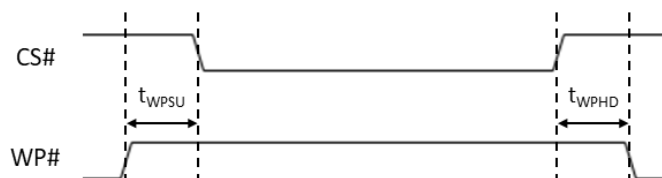
### 8.7.2 Synchronous Output Timing

**Figure 31: Synchronous Data Output Timing (SDR/DDR)**



### 8.7.3 WP# Timing

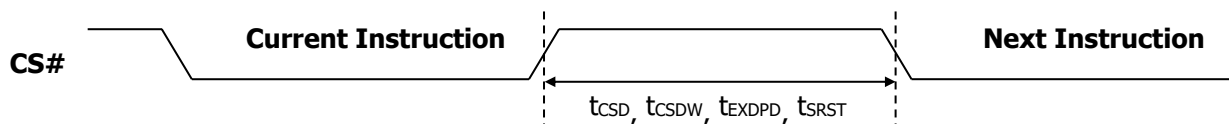
**Figure 32: WP# Operation Timing**



### 8.7.4 CS# High Time

CS# High time (the period during which CS# signal remains High) is divided into five timing based on operations.

- 1) CS# High time after any Read instructions, Write Enable/Disable, Enable Quad SPI/Extended SPI, No Operation and Software Reset Enable.
- 2) CS# High time after Write Memory instructions.
- 3) CS# High time after Write Register instructions or Augmented Area instruction.
- 4) CS# High time to deep power down exit.
- 5) CS# High time after JEDEC reset and software reset operation.



**Table 29: CS# High time after instructions**

| Parameter                                                                                                                              | Symbol      | Min               | Max. | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------|-------------|-------------------|------|------|
| CS# High time after any Read instructions, Write Enable/Disable, Enable Quad/Dual/Extended SPI, No Operation and Software Reset Enable | $t_{CSD}$   | 20                | -    | ns   |
| CS# High time after Write Memory instructions                                                                                          | $t_{CSDW}$  | Refer to Table 31 |      | -    |
| CS# High time after Write Register instructions or Augmented Area instruction                                                          | $t_{CSDW}$  | Refer to Table 32 |      | -    |
| CS# High time after deep power down exit command                                                                                       | $t_{EXDPD}$ | 25                | -    | us   |
| CS# High time after JEDEC reset and software reset                                                                                     | $t_{SRST}$  | 2.0               | -    | ms   |

**Notes:**

1. Read Status Register (05h) instruction is applicable during any CS# High period.

## 8.7.5 AC Timing Parameters

**Table 30: AC Timing Parameter**

| Parameter                                          | Symbol      | Min.                  | Max. | Units |
|----------------------------------------------------|-------------|-----------------------|------|-------|
| Clock Frequency – SDR                              | $f_{CLK}$   | 1                     | 150  | MHz   |
| Clock Frequency – DDR                              | $f_{CLK}$   | 1                     | 75   | MHz   |
| Clock Low Time                                     | $t_{CL}$    | $0.45 * 1 / f_{CLK}$  | -    | ns    |
| Clock High Time                                    | $t_{CH}$    | $0.45 * 1 / f_{CLK}$  | -    | ns    |
| CS# Setup Time                                     | $t_{CSS}$   | 5                     | -    | ns    |
| CS# Hold Time                                      | $t_{CSH}$   | 4                     | -    | ns    |
| CS# High Time after Any Instruction (except Write) | $t_{CSD}$   | 20                    | -    | ns    |
| CS# High Time after Write Instruction              | $t_{CSDWX}$ | Refer to Table 31, 32 |      | ns    |
| Data Setup Time                                    | $t_{SU}$    | 2                     | -    | ns    |
| Data Hold Time                                     | $t_{HD}$    | 2                     | -    | ns    |
| CLK Low to Output Valid                            | $t_{CO}$    | -                     | 7.0  | ns    |
| CLK to Output Hold Time                            | $t_{OH}$    | 2.0                   | -    | ns    |
| CLK Low to Output Low-Z (Read)                     | $t_{CLZ}$   | 2.0                   | -    | ns    |
| CS# High to Output High-Z                          | $t_{HZCS}$  | -                     | 6.0  | ns    |
| WP# Setup Time                                     | $t_{WPSU}$  | 20                    | -    | ns    |
| WP# Hold Time                                      | $t_{WPHD}$  | 20                    | -    | ns    |
| CS# High to Power-down mode                        | $t_{EDPD}$  | -                     | 1    | us    |
| CS# High to Power-down mode exit                   | $t_{EXDPD}$ | -                     | 25   | us    |
| CS# Low time to exit Power-down mode               | $t_{CSDPD}$ | 50                    | -    | ns    |
| JEDEC Reset or Software Reset Time                 | $t_{SRST}$  | -                     | 2.0  | ms    |

**Table 31: CS# High Time after Write Memory Instruction**

| Current Instruction<br>: Write Memory | Next Instruction<br>: Read or Write Memory | Symbol             | Operating Frequency, SDR |     |     |     |     |     |     |    | Units |
|---------------------------------------|--------------------------------------------|--------------------|--------------------------|-----|-----|-----|-----|-----|-----|----|-------|
|                                       |                                            |                    | 150                      | 133 | 125 | 108 | 100 | 83  | 66  | 54 |       |
| 1s-1s-1s                              | 1s-1s-1s, 1s-1s-4s                         | t <sub>CSDW1</sub> | 20                       | 20  | 20  | 20  | 20  | 20  | 20  | 20 | ns    |
| 1s-1s-1s                              | 1s-4s-4s                                   | t <sub>CSDW2</sub> | 140                      | 130 | 120 | 110 | 90  | 60  | 20  | 20 | ns    |
| 1s-1s-4s, 1s-4s-4s                    | 1s-1s-1s, 1s-1s-4s                         | t <sub>CSDW3</sub> | 110                      | 70  | 40  | 20  | 20  | 20  | 20  | 20 | ns    |
| 1s-1s-4s, 1s-4s-4s                    | 1s-4s-4s                                   | t <sub>CSDW4</sub> | 230                      | 200 | 190 | 140 | 110 | 60  | 20  | 20 | ns    |
| 4s-4s-4s                              | 4s-4s-4s                                   | t <sub>CSDW5</sub> | 270                      | 250 | 230 | 200 | 170 | 140 | 110 | 80 | ns    |

| Current Instruction<br>: Write Memory | Next Instruction<br>: Read or Write Memory | Symbol              | Operating Frequency, DDR |  |  |  |  |     |     |     | Units |
|---------------------------------------|--------------------------------------------|---------------------|--------------------------|--|--|--|--|-----|-----|-----|-------|
|                                       |                                            |                     |                          |  |  |  |  | 75  | 66  | 54  |       |
| 1s-1d-1d                              | 1s-1d-1d, 1s-1d-4d                         | t <sub>CSDW6</sub>  |                          |  |  |  |  | 20  | 20  | 20  | ns    |
| 1d-1d-1d                              | 1s-4d-4d                                   | t <sub>CSDW7</sub>  |                          |  |  |  |  | 100 | 60  | 20  | ns    |
| 1s-1d-4d, 1s-4d-4d                    | 1s-1d-1d, 1s-1d-4d                         | t <sub>CSDW8</sub>  |                          |  |  |  |  | 90  | 20  | 20  | ns    |
| 1s-1d-4d, 1s-4d-4d                    | 1s-4d-4d                                   | t <sub>CSDW9</sub>  |                          |  |  |  |  | 200 | 130 | 50  | ns    |
| 4s-4d-4d                              | 4s-4d-4d                                   | t <sub>CSDW10</sub> |                          |  |  |  |  | 270 | 220 | 160 | ns    |

**Notes:**

1. The frequency for 1s-1s-4s and 1s-4s-4s mode is limited to 108MHz.  
The frequency for 1s-1d-4d mode is limited to 54MHz.
2. The High CS# time after Write Memory instructions is strongly dependent on SPI mode and frequency.

**Table 32: CS# High Time after Register/Augmented Area Write Instruction**

| Current Instruction                                             | Next Instruction                                                                           | Symbol              | Min. | Units |
|-----------------------------------------------------------------|--------------------------------------------------------------------------------------------|---------------------|------|-------|
| Write Memory Instructions                                       | Read Register except for Status Register<br>Write Register<br>Read or Write Augmented Area | t <sub>CSDW11</sub> | 500  | ns    |
| Write Register Instructions<br>Write Augmented Area Instruction | Any Instructions except for Status Register                                                | t <sub>CSDW12</sub> | 1000 | ns    |

## 9. Thermal Resistance

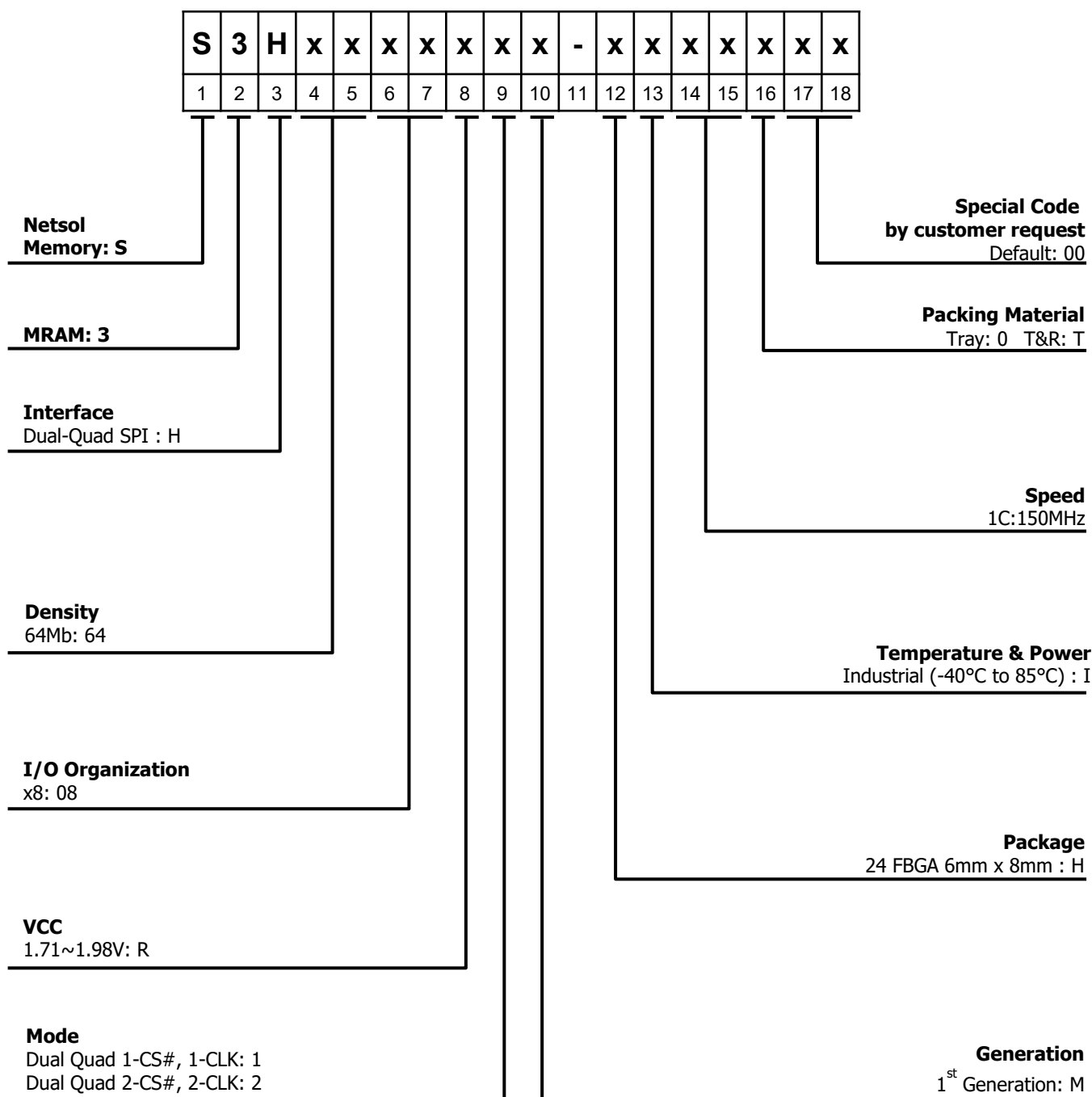
**Table 33: Thermal Resistance**

| Parameter     | Description                              | 24 FBGA | Unit |
|---------------|------------------------------------------|---------|------|
| $\theta_{JA}$ | Thermal resistance (junction to ambient) | 69.2    | °C/W |
| $\theta_{JC}$ | Thermal resistance (junction to case)    | 30.4    |      |

**Notes:**

1: These parameters are guaranteed by characterization; not tested in production.

## 10. Part Numbering System



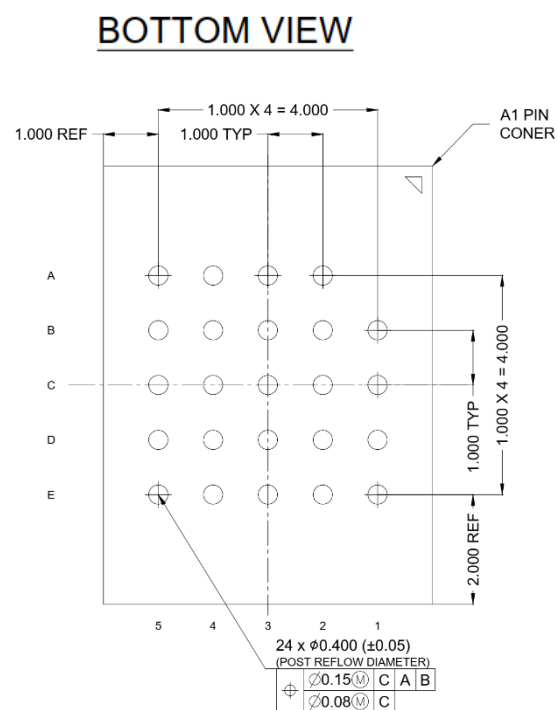
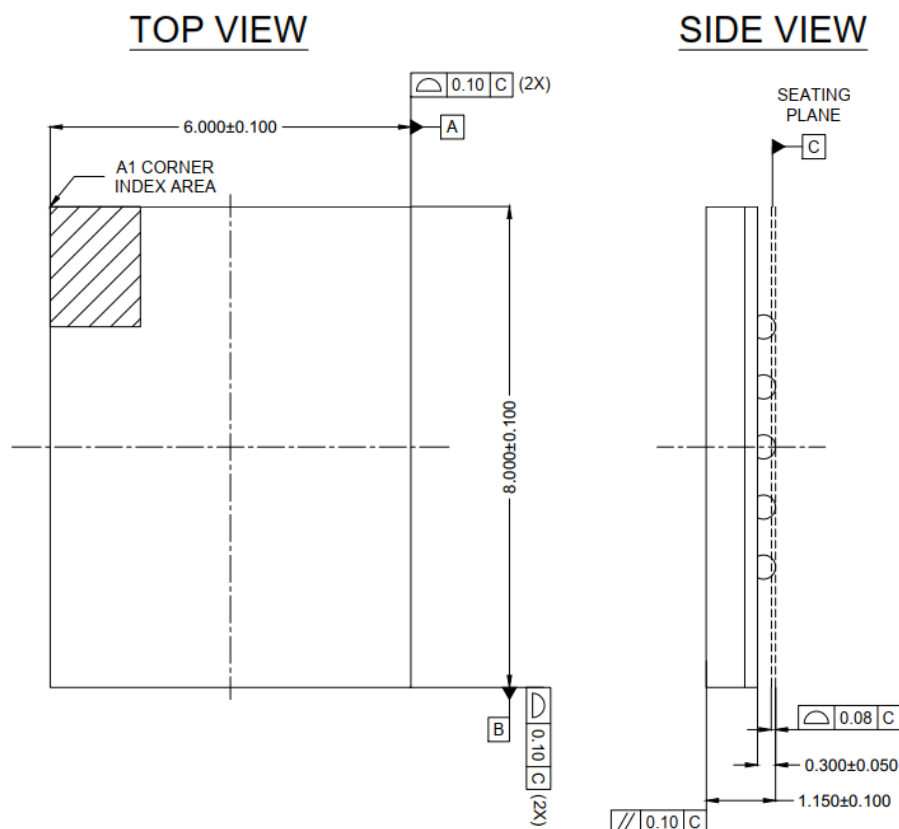
## 11. Ordering Part Numbers

**Table 34: Ordering Part Number**

| Temperature Grade | Operating Temperature | Package | Shipping Container | Ordering Part Number |
|-------------------|-----------------------|---------|--------------------|----------------------|
| Industrial        | -40°C to 85°C         | 24 FBGA | Tray               | S3H6408R1M-HI1C000   |
|                   |                       |         | Tape and Reel      | S3H6408R1M-HI1CT00   |
|                   |                       |         | Tray               | S3H6408R2M-HI1C000   |
|                   |                       |         | Tape and Reel      | S3H6408R2M-HI1CT00   |

## 12. Package Dimension

### 24-Ball FBGA (6mm x 8mm)



#### [Notes]

1. All Dimensions in Millimeters
2. RAW SOLDER BALL SIZE IS 0.40mm
3. SRO SIZE IS 0.35mm

## Revision History

| Revision | Date      | Description                                                                                                                                                                                                                           |
|----------|-----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0.1      | Mar. 2025 | Initial Release                                                                                                                                                                                                                       |
| 0.2      | May, 2025 | 1. Update Table 28: DC Characteristics<br>- Add the Reset Current and related notes                                                                                                                                                   |
| 0.3      | Jul. 2025 | 1. Change the Device Identification Register bit configuration in the Table 17:<br>- Change ID[15:12] from Temperature to Reserved<br>2. Update the Data Retention parameter (Table 24)<br>3. Correct a typo in the 24 FBGA dimension |

\* Products and specifications discussed herein are subject to change by Netsol without notice.